MOLECULAR DYNAMICS STUDIES OF
THIN FILM NUCLEATION AND SUBSTRATE MODIFICATION

By

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by

Yanhong Hu
This dissertation is dedicated to my family with love and gratitude.
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By

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August 2003

Chair: Susan B. Sinnott
Major Department: Materials Science and Engineering

Deposition of energetic particles on solid surfaces has found increasing application in surface science. However, the detailed surface chemistry and relevant atomic mechanisms are not well understood. Molecular dynamics (MD) simulations are an ideal method to study these processes atomistically because they usually occur on short time scales (of the order of a few picoseconds). In this dissertation, MD simulations are performed to investigate thin film formation through organic cluster beam deposition and chemical modification of carbon nanotube/polymer composites via polyatomic ion beam deposition.

The interatomic forces are calculated from the reactive empirical bond-order (REBO) potential for carbon-based systems coupled with the Lennard-Jones potentials. The reliability of this approach is examined by comparing its predictions for ethylene-cluster beam deposition with the results of a more accurate order-N nonorthogonal tight-
binding method. The results show that the REBO potential captures the general characters of the relevant chemistry.

The deposition processes of interest occur at room temperature; hence, appropriate temperature control methods must be employed in the simulations. A comparison study of four temperature control methods during the simulation of cluster deposition finds that the generalized Langevin equation approach is sufficient for dissipation of excess system energy if the deposition occurs on a large enough substrate at a moderate incident energy (< 40 eV/cluster-atom). A new temperature control method has been developed for use at higher incident energies.

In the simulations of thin film formation through organic cluster beam deposition, the dependence of the results on the intracluster bonding, incident angle and deposition direction is examined. Beams of ethylene clusters, adamantane molecules, and C_{20} molecules are thus deposited on a diamond surface with varying lateral momenta along two different crystallographic orientations at various incident angles.

The simulations of chemical modification of carbon nanotube/polystyrene composites via ion beam deposition predict that this process can effectively induce the formation of cross-links between otherwise unfunctionalized nanotube and polystyrene chains. Modification efficiency is shown to depend on the incident energy and the composite structure. The responses of the composites to ion beam deposition are different from the response of pristine polystyrene. The simulations detail the atomic-scale mechanisms that are responsible for these findings.
CHAPTER 1
INTRODUCTION

Molecular simulation is a relatively new technique, which became known to people only in the early 1950s. Since then, it has developed rapidly into a valuable tool in scientific research, complementing both analytical theory and experiment. One major application field of molecular simulations is materials science. Materials science deals with the properties of systems of many atoms or molecules. The interactions between these atoms or molecules determine the overall properties. Therefore, accurate descriptions of these interactions are critical to understand the properties of the material.

When they are based on the laws of quantum mechanics, molecular simulations can provide essentially exact estimations of the interatomic interactions by explicitly considering the electrons and nuclei. Of course quantum mechanical calculations of interatomic interactions are very complicated and can only be done using computers. Such simulations involve few approximations and are usually known as *ab initio* or first principles simulations. *Ab initio* simulations can thus be used to predict unknown properties of a material or can be used as a test of an approximate analytical theory by comparing the result of the simulation with the prediction from the theory.

Computational demands can be dramatically reduced if some approximations are introduced into the description of the interatomic interactions through the use of appropriate empirical functional forms. However, the results of such classical simulations may contain errors. Depending on how many approximations are introduced, these simulations are termed either semi-empirical or empirical. Between the two, empirical
simulations may contain more errors because more approximations are employed. In these cases, the simulation predictions from a microscopic model should be compared with experimental or more exact \textit{ab initio} results. If the model turns out to be a good one, then the simulation can be used to provide atomic insights and assist in the interpretation of experimental results.

The two most important molecular simulation methods are the Monte Carlo (MC) method and the method of molecular dynamics (MD). The MC method uses probability laws and random numbers (hence the name “Monte Carlo”) to obtain the ensemble average and standard deviation of a random variable via random sampling.\cite{1} The first MC simulation was carried out by von Neumann, Ulam, and Metropolis at the end of World War II to study the diffusion of neutrons in fissionable material. The MC method is a statistical method, and any problems involving random processes can essentially be simulated via this method. Assuming the applicability of classical mechanics, MD simulation is a deterministic method in which the system evolves according to Newton’s equations of motion.\cite{2} Thus, MD simulations can give full dynamical information and can be used to study time-dependent phenomena. Both MC and MD methods have advantages and disadvantages. Although MD is the only reliable method to study time-dependent properties, conventional MD can only track processes for at most a few nanoseconds. In contrast, MC method is not subject to time limits and can yield thermodynamic properties that may not easily be obtained from MD. Depending on the problem and properties of interest, either MC or MD, or sometimes a combination of MC and MD, is used in an atomistic simulation.
The purpose of molecular simulations is to model the macroscopic sample and provide information that is not easily detectable from experiments. Unfortunately, due to the computational limitations of present-day computers, the number of atoms that can be conveniently handled ranges from a few hundred to a few million. This number is still far removed from the real size systems, which contain Avogadro’s number \(6.023 \times 10^{23}\) of particles. In order to model a macroscopic system in terms of a finite simulation system of \(N\) particles, periodic boundary conditions are employed. This idea can be illustrated by Figure 1-1, in which the simulation system of \(N\) particles is treated as a basic unit and is replicated throughout space. Therefore, the simulation unit is essentially embedded in an infinite array of units, all with the same geometrical arrangement of particles. The application of periodic boundary conditions has two obvious advantages. Without periodic boundary conditions, the simulation system would simply terminate and be surrounded by surfaces. The surface atoms have fewer neighbors than the atoms inside. For a simulation system containing finite number of atoms that is negligible compared with the real size system, the ratio of its surface atoms to the total number of atoms would be much larger than in reality. In other words, surface effects would appear to be much
more important than what they should be. Thus, the first advantage of the application of periodic boundary conditions is that the surface effects, which would otherwise be proportional to $N^{-1/3}$, are reduced to be proportional to $N^{-1}$.\cite{2, 3} Second, as the simulation progresses, for every molecule that leaves the simulation unit, its image will enter through the opposite face. Thus, the volume and the density of the simulation unit can be maintained throughout the simulation. Although the use of periodic boundary conditions has been proved to be surprisingly effective and successful, it should be noted that such boundary conditions may lead to correlations not present in the real system.\cite{2} The point is that the basic simulation unit should be large enough so that those correlations will not introduce spurious effects.\cite{4}

In molecular simulations, the key is the calculation of the interactions between the particles, which, in principle, should include not only the interactions between the particles contained in the simulation system, but also all the interactions between the particles and their images once the periodic boundary conditions are employed. Even if empirical functions are used to model these interactions, the computational load is still impractically high. Under circumstances like these, appropriate cutoff distances ($r_c$) should be used to truncate the interactions between the particles. This means that the effects of the particles beyond a certain cutoff distance are ignored. While this simplification certainly will introduce error into the calculation, the error can be made arbitrarily small by choosing a large enough $r_c$.\cite{2} The introduction of the cutoff distance is especially meaningful for short-range interactions such as covalent bonding, where interactions between neighboring particles dominate.
Although the use of a cutoff distance saves tremendous computational time, a significant amount of CPU time is still spent calculating the distance between the particles at every step. In order to reduce the unnecessary labor, for instance, in calculating the distance between two particles that are obviously too far apart to interact every time, a “neighbor list” table is constructed, which was an idea first introduced by Verlet. The table stores each particle’s neighbors and is updated only at predetermined time intervals. The neighbors include all the particles that are within a certain distance $r (> r_c)$ from each particle. The program updates the neighbor list table only when considerable displacements beyond $r$ occur. With the introduction of the neighbor list table, the calculation of the interaction energy between the particles now can be performed by only scanning through the particles listed in the table instead of scanning through all the particles. Depending on the problem that needs to be solved, some modified “neighbor list” techniques that update the table more efficiently have been reported.

Many processes are carried out experimentally at constant temperatures. In order to model these processes, the temperature of the simulation system should be controlled. This is achieved by employing thermostat atoms. Thermostat atoms have special constraints such as extra frictional forces placed upon them, and evolve differently from the other ordinary atoms as the simulation progresses. The function of these thermostat atoms is to remove extra energy from the simulation system or to compensate for a loss of energy, depending on which is necessary to maintain the system temperature. There have been several algorithms proposed for temperature control, such as the velocity
rescaling scheme, the Nosé-Hoover method, and the generalized Langevin equation approach.

In this dissertation, thin film nucleation through organic cluster beam deposition and chemical functionalization of carbon nanotube/polymer composites via polyatomic ion beam deposition are investigated using molecular simulations. Since the phenomena of interest are time-dependent and both deposition processes are rapid enough that they occur within a few picoseconds ($10^{-12}$ seconds), molecular dynamics simulations are used in both cases.

### 1.1 Molecular Dynamics Simulations

In classical mechanics, Newton’s second law states that in order to make a body of mass $m$ undergo an acceleration $a$, a force $F$ is required that is equal to the product of the mass times the acceleration:

$$ F = ma $$  \hspace{1cm} (1-1)$$

This equation can also be expressed in terms of the position vector $\mathbf{r}$ of the body as

$$ F = m \frac{d^2 \mathbf{r}}{dt^2} $$  \hspace{1cm} (1-2)$$

This is the basis of molecular dynamics (MD). Knowing the force $F$, based on Equation (1-2), we can thus study the trajectory of each particle in space and investigate the time-dependent properties. The problem is how to calculate the force. From the principle of conservation of energy, we know that the kinetic energy ($\frac{1}{2}mv^2$) and the potential energy ($U$) of the body can vary, but their sum ($\varepsilon$) is a constant.

$$ \frac{1}{2}mv^2 + U = \varepsilon $$  \hspace{1cm} (1-3)$$

In terms of $\mathbf{r}$, equation (1-3) can be expressed as
\[ \frac{1}{2} m \left( \frac{d\mathbf{r}}{dt} \right)^2 + U = \varepsilon \]  

(1-4)

Differentiating both sides of Equation (1-4) with respect to time, we find

\[ \frac{d}{dt} \left[ \frac{1}{2} m \left( \frac{d\mathbf{r}}{dt} \right)^2 + U \right] = 0 \]

and so

\[ m \frac{d\mathbf{r}}{dt} \cdot \frac{d^2\mathbf{r}}{dt^2} + \frac{dU}{dt} = 0 \]

This can be rewritten as follows because potential energy is a function of the position \( U(\mathbf{r}) \):

\[ m \frac{d\mathbf{r}}{dt} \cdot \frac{d^2\mathbf{r}}{dt^2} + \nabla U \cdot \frac{d\mathbf{r}}{dt} = 0 \]

Therefore, we get

\[ m \frac{d^2\mathbf{r}}{dt^2} = -\nabla U \]

Referring back to the Newton’s second law (Equation (1-2)), the left side of the above equation is the force. Thus, the force can be calculated from the potential energy:

\[ \mathbf{F} = -\nabla U \]  

(1-5)

The potential energy, as stated before, can be obtained using either empirical potential energy expressions, semi-empirical methods, or exact ab initio approaches. In MD simulations, the calculations of the potential energy and force are the most time-consuming parts. Once the force is obtained, Equation (1-2) can be integrated to follow the time evolution of the atoms in response to the applied forces.

In practice, numerical integrations instead of algebraic solutions to Equation (1-2) are performed. There are several numerical methods for integrating Newton’s equations,
including the Verlet algorithm, the leapfrog algorithm and the predictor-corrector algorithm.\cite{2} In our MD simulations, the predictor-corrector algorithm is used. Based on Taylor’s expansions, if the position \( \mathbf{r} \), velocity \( \mathbf{v} \), acceleration \( \mathbf{a} \) and time derivative of the acceleration \( \mathbf{b} \) are known at time \( t \), these quantities can be obtained at \( t + \Delta t \) (\( \Delta t \) is the time-step), as shown in the following equation:

\[
\begin{align*}
\mathbf{r}^p(t + \Delta t) &= \mathbf{r}(t) + \Delta t\mathbf{v}(t) + \frac{1}{2}(\Delta t)^2 \mathbf{a}(t) + \frac{1}{6}(\Delta t)^3 \mathbf{b}(t) + \cdots \\
\mathbf{v}^p(t + \Delta t) &= \mathbf{v}(t) + \Delta t\mathbf{a}(t) + \frac{1}{2}(\Delta t)^2 \mathbf{b}(t) + \cdots \\
\mathbf{a}^p(t + \Delta t) &= \mathbf{a}(t) + \Delta t\mathbf{b}(t) + \cdots \\
\mathbf{b}^p(t + \Delta t) &= \mathbf{b}(t) + \cdots 
\end{align*}
\]

If we use the truncated Taylor expansion, where the terms higher than those shown explicitly in Equation (1-6) are ignored, all four quantities can thus be “predicted.” However, no force law has been taken into account so far, and the predicted values are not based on physics. This deficiency is remedied at the “corrector” step. Knowing the new position \( \mathbf{r}^p \) at time \( t + \Delta t \), we are able to evaluate the new potential energy, and thus the force at \( t + \Delta t \) is obtained. Then, from Equation (1-1), the corrected acceleration \( \mathbf{a}^c(t + \Delta t) \) can be calculated. Comparing this corrected acceleration with the predicted one, the error at the prediction step can be evaluated as

\[
\Delta \mathbf{a}(t + \Delta t) = \mathbf{a}^c(t + \Delta t) - \mathbf{a}^p(t + \Delta t)
\]

This term is then used to correct all the predicted quantities as follows:

\[
\begin{align*}
\mathbf{r}^c(t + \Delta t) &= \mathbf{r}^p(t + \Delta t) + c_0 \Delta \mathbf{a}(t + \Delta t) \\
\mathbf{v}^c(t + \Delta t) &= \mathbf{v}^p(t + \Delta t) + c_1 \Delta \mathbf{a}(t + \Delta t) \\
\mathbf{a}^c(t + \Delta t) &= \mathbf{a}^p(t + \Delta t) + c_2 \Delta \mathbf{a}(t + \Delta t) \\
\mathbf{b}^c(t + \Delta t) &= \mathbf{b}^p(t + \Delta t) + c_3 \Delta \mathbf{a}(t + \Delta t)
\end{align*}
\]
These values are now better approximations to the true quantities, and are used to predict the quantities in the next iteration. The corrector constants $c_i$ are chosen to yield an optimal compromise between the accuracy and the stability of the algorithm.[2] Gear discussed the best choice for these constants, which depends on the order of the differential equations and of the Taylor series.[8] These constants are fixed for a given order algorithm. For instance, the one we use is a third-order Nordsieck predictor-corrector algorithm, and the values for $c_i$ are $c_0 = \frac{1}{6}$, $c_1 = \frac{5}{6}$, $c_2 = 1$, and $c_3 = \frac{1}{3}$. Figure 1-2 schematically shows the predictor-corrector MD procedures used in the simulations described in this dissertation.

In MD simulations, short time-steps are required to yield reliable results. There are at least two reasons for this. One is due to the quick motion of the atoms (for example, the time-scale of atomic vibrations is typically $10^{-13}$ s[9]). In order to capture atomic motions accurately, as MD simulations desire to do, the time-step must be much smaller than the frequency of the atomic motions. The second reason is that, from the integration point of view, a small $\Delta t$ is necessary to achieve the predictions calculated in Equation (1-6) as accurate as possible. Usually, time-steps on the order of a femtosecond ($10^{-15}$ s) are used. Unfortunately, such short time-steps make the modeling of processes that occur on time-scales larger than a few nanoseconds out of the reach of conventional MD simulations on present-day computers.

MD simulations can generate atomistic information such as atomic positions and velocities. Via statistical mechanics, this atomistic information can be related to macroscopic quantities such as pressure, temperature, heat capacities, etc. Therefore, MD
Figure 1-2. Flowchart of the predictor-corrector MD.

Simulations can be used to study these thermodynamic properties as well as time-dependent (kinetic) phenomena. The first MD simulation was done by Alder and Wainwright to study the dynamics of an assembly of hard spheres.\textsuperscript{[10, 11]} Their studies provide many important insights concerning the behavior of simple liquids. The first MD simulation of a real material was carried out by Gibson et al. to model radiation damage in crystalline Cu.\textsuperscript{[12]} In 1964, Rahman performed the first MD simulation using a realistic potential for liquid argon.\textsuperscript{[13]} Since then, MD simulations have been widely used in
studying solids, liquids, gases, simple and complex hydrodynamic flows, shock waves, deformation and fracture of materials, chemistry in solutions, conformational changes of proteins, etc. MD simulations also find application in experimental procedures such as X-ray crystallography, NMR structure determination, and inelastic neutron scattering.\[14\]

1.2 Cluster Beam Deposition on Solid Substrate

Clusters typically contain 10 to several thousand atoms. Weakly bound van der Waals clusters (e.g., noble gas clusters), covalently bound clusters (e.g., fullerenes), as well as ionic and metallic clusters have been observed. As an aggregate of atoms and/or molecules, the cluster is a new state of matter that lies between isolated atoms/molecules and the condensed phase of bulk matter. Due to their high surface-to-volume ratio, clusters display peculiar properties that differ considerably from those of the constituents and the bulk material. The properties depend strongly on the number of atoms in the cluster. By controlling the size of the clusters and other operating variables, such as the incident energy and substrate temperature, cluster deposition on solid substrates can produce thin films with specific structures and properties.

1.2.1 Thin Films from Cluster Beam Deposition

Clusters can be generated in jet and beam experiments in both continuous and pulsed forms.\[15\] In cluster formation, control of cluster type (noble gases, covalently bound molecules, metals, etc.), cluster size, and cluster energy are the major objectives.

In 1956, Becker announced the formation of free jet cluster beams of room temperature gases (Ar and He) produced by expansion through cooled nozzles into a vacuum environment.\[16\] Such gas expansions through small nozzles, sometimes with a carrier gas, are effective sources of molecular gas clusters. For the clusters formed from
these gas expansion sources, the control of pressure and temperature of the stagnation gas helps to control the cluster size.

Another category of cluster sources, gas aggregation sources, are reported to be particularly suitable for production of metal clusters of up to thousands of atoms.\textsuperscript{[17-19]} Briefly, metal vapor is first produced by either thermal evaporation\textsuperscript{[18]} or sputter discharge.\textsuperscript{[19]} The vapor is then projected into a condensation cell filled with cold rare gas. The supersaturated vapor then nucleates and coalesces to form clusters, the size of which is controlled by adjusting the carrier gas flow.

Laser vaporization source is especially suitable for generating cluster beams of refractory materials.\textsuperscript{[15]} Laser ablation of solids produces plasma via the localized heating induced in the material. By rapid quenching of the plasma, clusters can be produced. This technique was originally used by Smalley (as cited in “Milani and Iannotta\textsuperscript{[15]}”) and led to the discovery of fullerenes C\textsubscript{60} and C\textsubscript{70} in a molecular beam experiment in which laser vaporized graphite was seeded and expanded in helium.\textsuperscript{[20]} The size of the clusters generated from the laser vaporization sources is determined by controlling the mean residence time of the plasma-gas mixture.\textsuperscript{[21, 22]}

Ionized clusters are usually generated by electron impact after cluster formation. Photon ionization of clusters, for instance, by UV lasers, is also reported.\textsuperscript{[15]} The purpose of ionization the clusters is to achieve easy manipulation and detection of the cluster energy using electromagnetic fields. As far as the effect of ionization on the deposition results is concerned, ionized clusters are widely assumed to behave in a similar manner to neutral clusters due to the low charge carried in each cluster.\textsuperscript{[23]} The deposition of size- and energy-selected clusters is the ultimate goal for the synthesis of nanocrystalline
materials with tailored properties. Although the deposition of size-selected clusters in bulk quantities is still in development, controlled deposition of clusters to study clustersurface and cluster-cluster interactions in the sub-monolayer regime have been realized using mass/energy filters.[15]

The past three decades have witnessed an exciting development in thin film production through energetic cluster-surface collisions using methods such as ionized cluster beam deposition (ICBD),[24-32] energetic cluster impact (ECI),[19] and low-energy cluster beam deposition (LECBD).[22, 33, 34] The whole collision process occurs rather rapidly, typically within a few picoseconds.[35] Thin film formation from energetic cluster beam deposition has several advantages over traditional atomic ion beam deposition.[19, 23] These include a high, transient concentration of energy and mass that is deposited in a very localized region of the surface, resulting in conditions of extreme temperature and pressure under which novel chemical reactions may happen.[28, 36, 37] In addition, compact, smooth and strongly adhering thin films can easily be made on low temperature substrates. Since the charge/atom ratio of ionized clusters is very low, space-charge problems are negligible. Another intriguing feature of energetic cluster beam deposition is that the surface modification effect is restricted to a very shallow region of the substrate, avoiding significant property changes to the bulk material. Revealed by MD simulations, the reason is the collective “plunger” effect of a number of cluster atoms interacting with the same substrate atom at the same time.[38]

When the deposition occurs at high incident energy (in the range of keV per cluster), the clusters will experience dramatic morphological changes upon impact. A variety of outcomes are possible, including scattering of cluster fragments, sputtering of
substrate materials, implantation of cluster atoms, adhesion of the cluster to the surface, and lateral motion of cluster atoms. These phenomena are summarized in Figure 1-3.\textsuperscript{[26]}

When the clusters are deposited with an incident energy high enough to stick to the substrate but low enough to maintain their original structure, so-called cluster assembled materials are produced.\textsuperscript{[34]} This technique is known as low energy cluster beam deposition (LECBD). The incident energy is typically less than 0.1 eV/atom in LECBD (in ICBD and ECI, the energy is usually larger than 1 eV/atom).\textsuperscript{[39]} The LECBD technique is fascinating because the generated thin films keep a “memory” of the free-cluster phase and the clusters essentially act as building blocks. Therefore, this technique offers a unique opportunity to prepare thin films from “building blocks” that have been well controlled in the gas phase.\textsuperscript{[34]}

![Figure 1-3. Possible phenomena that may occur after the deposition of energetic clusters on a solid substrate.\textsuperscript{[26]}](image)

The group at Kyoto University pioneered thin film creation through the high energetic cluster beam deposition.\textsuperscript{[24, 27]} The technique they developed is generally known as ionized cluster beam deposition (ICBD). Since its development, ICBD has been widely used to produce thin films from the deposition of a variety of materials, such as metals,\textsuperscript{[24,}
nitrides, semiconductors, and organic materials. However, theoretical calculations show that standard ICBD conditions do not favor the formation of clusters. Experimentally, it was claimed that small clusters of up to 25 atoms might exist in the clusters produced from a typical ICBD sources, but there was no or a very small fraction of large clusters.

Energetic cluster impact (ECI) is a technique developed by Haberland’s group in Freiburg. Figure 1-4 demonstrates the experimental set-up of thin film deposition by ECI. The size of the clusters formed ranges from 50 to more than $10^6$ atoms per cluster. What is unusual in this technique is that a large percentage (30-80%) of these clusters has already been ionized; therefore, no additional electron ionization step is necessary. The cause for this simultaneous ionization is the use of the magnetron cathodes (C1 and C2 in Figure 1-4), which not only help to generate vapor by sputtering, but also ionize the clusters by the afterglow from the sputter discharge. Thin films from
the deposition of metal (Mo, Cu, Al, and stainless steel) and SiO$_2$ on Si and glass substrates at room temperature using ECI have been reported so far.$^{19,42}$ The incident energy of the clusters is shown to be critical in determining the quality of the resultant film.

In the past 30 years, a large amount of effort has been spent in understanding thin film deposition from cluster-solid collisions. Although phenomenological models derived from experimental observations can explain some of the relationships between deposition conditions (incident energy, cluster size, and substrate temperature) and the resulting film properties and structures, a deep enough understanding and, even more importantly, the ability to predict how a change in deposition conditions leads to a change in thin film properties, still remain as a longstanding challenge. This challenge has resulted in the exploration of computer simulation, which has been proved to be a predictive as well as explanatory tool in many cases. Among the various simulation techniques that may be used, MD simulation is especially well suited to study the energetic deposition of clusters because this process typically occurs within a few picoseconds. MD simulations allow one to view the atomic motions and alter conditions of the system that may not be easily varied experimentally. Therefore, simulations can provide valuable information about the atomic mechanisms responsible for the resulting properties and structures. An added feature of MD simulations is that quantities comparable to experimental results can be obtained, especially after the breakthrough development of atomic scale experimental techniques, such as atomic force microscopy (AFM) and scanning tunneling microscopy (STM).
The first MD simulation of cluster-surface collisions was made by Müller with a two-dimensional model using Lennard-Jones potentials.\cite{43} Albeit simple, his simulations disclosed the important role played by the cluster energy per atom in the quality of the thin film. Following Müller’s lead, researchers around the world, including those who developed the experimental cluster deposition techniques, performed a variety of MD simulations, sometimes in combination with experimental work. The nucleation and growth of the thin films,\cite{44-49} evolution of clusters after impact,\cite{35, 44, 46, 50-57} defect formation in the substrates,\cite{46-48, 58-61} and film morphology,\cite{42, 62-64} have been examined and documented. These MD simulations provide atomic scale insights into the effects of cluster energy,\cite{47, 48, 65-73} cluster size,\cite{67, 74} and substrate temperature\cite{67, 75-77} on the resultant film structures and properties. As expected, these investigations further people’s understanding of the underlying reaction mechanisms\cite{36, 53, 59, 78, 79} as well as the thin film nucleation\cite{44, 46, 49, 80, 81} and defect formation mechanisms.\cite{59} Together with the experimental studies, these MD simulations help to provide a comprehensive picture of cluster-solid interactions.

1.2.2 Motivation and Objectives

Among various thin films, organic thin films are technologically important especially in electronic and optical device applications. For example, organic electroluminescent (EL) devices can produce a strong light emission with a direct current of relatively low voltage.\cite{82} Additionally, deposition of organic materials can make diamond-like carbon films,\cite{83-86} which have many characteristics of bulk diamond including extreme hardness and high thermal conductivity.

Conventional solvent-free methods to make organic thin films include physical vapor deposition (PVD) and chemical vapor deposition (CVD).\cite{82-88} Nevertheless, these
methods are not effective at achieving crystalline structures in the deposited films, and hence, the desired properties are not obtained.\cite{30} Energetic cluster beam deposition, however, appears to be successful in this respect.\cite{30} In fact, polyethylene thin films with a structure close to the single crystalline polyethylene,\cite{25} tetraphenylporphine thin films with preferential crystal orientation,\cite{28} and anthracene thin films with superior photoluminescent and electroluminescent properties\cite{25} have been reported using energetic cluster beam depositions. The researchers at Charles University found that cluster beam deposition could produce phthalocyanine thin films with structures and properties ranging from those of evaporated films to the plasma polymerized samples.\cite{29} These studies indicate that cluster beam deposition is indeed a versatile and promising technique to prepare organic thin films for functional devices.

Despite the impressive experimental work in organic thin film formation through energetic cluster-solid collisions, there is little fundamental understanding of the reaction and film nucleation mechanisms that occur during organic cluster deposition. These problems can be addressed in MD simulations. Although a large amount of simulation work has been carried out to study cluster-solid collisions as mentioned before, most deal with metallic clusters\cite{35, 42, 46-48, 52, 54, 56, 57, 60, 62, 64, 71-73, 77, 80, 81} or noble gas clusters.\cite{43-45, 50, 51, 53, 61, 66, 78, 79, 89, 90} MD simulations of the deposition of fullerene molecules, i.e., carbon clusters, have also been reported.\cite{36, 63, 65, 66, 70, 75, 91-94}

For the last six years, the Sinnott group has used MD simulations to study the deposition of organic clusters on diamond surfaces.\cite{95-105} The clusters that have been considered include organic molecular clusters of ethane,\cite{95} ethylene,\cite{95, 96, 100, 101} acetylene,\cite{95-100} and adamantane.\cite{102} Both single cluster deposition and cluster beam
deposition have been examined. The simulations show that due to the deposition-induced high system temperature and pressure, numerous addition reactions may occur among the incident molecules and between the impact cluster and the surface when the incident energy is within 3 eV/molecule of the binding energy of a single cluster molecule.\[95\] This prediction is supported by the experimental work of Lyktey et al., who showed that polyethylene could be made from energetic collisions of molecular clusters of ethylene in the gas phase;\[106\] and Sakashita et al., who reported that solid-state polyacetylene was produced under high pressure.\[107\] These simulation studies have also addressed the dependence of film nucleation and growth on deposition conditions such as molecular reactivity,\[95, 100\] cluster size,\[99, 101\] incident energy,\[95, 96, 102\] impact frequency,\[97\] surface reactivity,\[98, 100\] and surface temperature.\[100, 101\] The formation of craters on the surface has been considered as well. These craters were found to be able to activate some surface atoms and promote the adhesion of clusters. These simulation results are in agreement with the reported cluster beam deposition experiments for making organic thin films.\[25, 28, 30\]

Varying the angle of incident particles has pronounced effects on the growing film morphology and properties. This has been shown in both simulations\[64, 108-112\] and experiments.\[113-118\] For instance, in vacuum evaporation, the oblique incidence of vapor atoms is found to result in thin films with anisotropy in various macroscopic properties, such as magnetic properties, electrical resistance, optical and mechanical properties.\[119\] In atomic ion beam deposition, the non-perpendicular incidence leads to non-local shadowing, which is the source of the resulting porous and columnar growth morphology.\[108, 113, 114\] The incident angle of atomic ion beams is also found to influence
thin film composition\cite{110, 115} surface-trapping probability\cite{117} and kinetic energy distribution of the sputtering surface fragments\cite{116}. Deposition of energetic cluster beams also shows that the surface smoothing effect\cite{64, 111, 118} and the sputtering effect\cite{118} are strongly affected by incident angle.

Although extensive simulations have been done by the Sinnott group in investigating the deposition of organic clusters, the effect of incident angle has not been considered previously. Therefore, one of the objectives of the study reported in this dissertation is to investigate angle effects on the deposition of organic clusters. Since a crystalline substrate is used in the simulations, film nucleation and growth at oblique deposition angles may have crystallographic orientation dependence, which is another factor examined here. One of our previous studies investigated the deposition of an adamantane cluster beam, while all the rest focused on clusters where the constituent molecules were weakly bonded through van der Waals interactions. In this dissertation, clusters with different types of chemical bonding holding the incident particles together are considered. It is the intention of this study to provide a more complete description of thin film nucleation and growth from energetic organic cluster beam depositions.

1.3 Carbon Nanotube/Polymer Composites

Carbon nanotubes posses unique structural, electrical, and thermal properties\cite{120-129}. Recent developments in the synthesis of carbon nanotubes have improved both their quality and quantity\cite{130-133}. These advances have paved the way for the expected new material applications of carbon nanotubes. Particular effort has been spent in making nanocomposites using these quasi-one-dimensional nanostructures as reinforcement to capitalize on their extraordinary mechanical properties on a macroscopic scale.
1.3.1 Carbon Nanotubes

Carbon nanotubes, also known as tubular fullerenes, consist of sp²-bonded carbon atoms. They were first reported in 1991 by Sumio Iijima[134] who was studying the material deposited on the cathode during the arc-evaporation synthesis of fullerenes.[135] Depending on the conditions under which they are produced, carbon nanotubes can assemble either as multi-layered co-axial tubes (multiwalled nanotubes, MWNTs) or as single-layer tubes (single-walled nanotubes, SWNTs). Each layer of the carbon nanotube can be thought of as a cylinder rolled from a sheet of graphite, as shown in Figure 1-5. Depending on the growth process, the lengths of carbon nanotubes can vary from approximately 100 nm to several microns and the diameters can range from 1 to 20 nm. The manner in which the graphene sheet is rolled into the cylinder can produce carbon nanotubes of various helical structures. As illustrated in Figure 1-6, the “rolling up” can be performed by adding the integer lattice vectors \( m \) and \( n \) together and then placing the tail and head of the resulting vector on top of each other.[132] As a result, zigzag nanotubes have vectors \( (n, 0) \) or \( (0, m) \), while armchair nanotubes have vectors \( (n, n) \). These are the two achiral nanotubes; all other vectors \( (n, m) \) correspond to chiral nanotubes.

![Figure 1-5. A graphene sheet rolled into a single-walled carbon nanotube (SWNT).](image)
The three most common methods to produce carbon nanotubes are the arc, laser, and chemical vapor deposition techniques. The standard carbon arc-evaporation method can make carbon nanotubes in large quantities by carefully choosing the type and pressure of the gas surrounding the arc, and the cooling of the electrodes and the chamber. However, in this way, only MWNTs are produced. By introducing metal catalysts such as Co, Fe, or Ni into the carbon arc, significant quantities of SWNTs are formed. In 1996, Smalley’s group found an alternative way to prepare SWNTs. It involved the laser vaporization of graphite and resulted in a high yield of SWNTs. These tubes tended to form aligned bundles (ropes) and had unusually uniform diameters (~1.4 nm). Chemical vapor deposition (CVD) provides more controllable routes to produce nanotubes with defined properties. The general nanotube growth mechanism in a CVD process involves the dissociation of hydrocarbon molecules (such as C\textsubscript{2}H\textsubscript{2},
C₂H₄, xylene, benzene, toluene, etc.) catalyzed by transition metal, and dissolution and saturation of carbon atoms in the metal nanoparticle.[133]

The synthesized carbon nanotubes are often found to be capped at the ends. The “caps”, different from the sidewall that is mainly made up of hexagonal rings, contain pentagons and heptagons (Figure 1-7).[140] These non-hexagonal rings help to introduce curvature as well as strain into the tube caps.

![Figure 1-7. A model of a capped SWNT.[140]](image)

The as-produced nanotubes often come with a number of impurities whose type and amount vary with synthesis methods and conditions. For example, Figure 1-8 shows a TEM image of a SWNT surrounded by catalyst particles and amorphous carbon. Carbonaceous impurities, such as amorphous carbon nanoparticles and soot, are the most common impurities.[130, 138, 141] The early gas phase purification method, which burnt the crude nanotubes in the oven and simultaneously blew air or oxygen through the system, only resulted in a very low yield (about 1%) of pure nanotubes.[142] One possible reason for this is the uneven burning of the sample. Therefore, liquid phase purification methods on well-dispersed samples were tried. It was discovered that by using oxidants such as H₂NO₃/ H₂SO₄[143] or an acid solution of potassium permanganate (KMnO₄),[144] the amorphous carbon and other impurities could be washed away effectively. The yield of pure tubes could be as high as 50%.[144] Nanotubes can survive harsh oxidation environments because, like graphite, nanotube walls are relatively inert. However, this is
not the case for the caps due to the strain and high degree of curvature in those regions.\textsuperscript{[145]} As a result, the purified nanotubes are opened at the ends.\textsuperscript{[143, 144]} The dangling bonds at the ends are usually stabilized by bonding with carboxyl or hydroxide groups.

![Figure 1-8. A SWNT formed in the catalytic carbon arc method.\textsuperscript{[141]}](image)

The reason why carbon nanotubes have attracted wide attention since their discovery is their unusual electrical, mechanical, and thermal properties associated with their unique structures. For example, they could be insulating, semi-conducting, or metallic depending on their diameter and chirality. This property was first predicted theoretically\textsuperscript{[146-149]} and then verified experimentally.\textsuperscript{[150, 151]} The sp\textsuperscript{2} carbon-carbon bond in the basal plane of graphite is the strongest of all chemical bonds,\textsuperscript{[135]} but the weakness of the interplanar forces make ordinary graphite impossible to be used as a structural material. Because of carbon nanotube’s highly perfect graphene structure, the mechanical stiffness and strength of carbon nanotubes are expected to be very high. It was initially difficult to directly probe the mechanical properties of individual nanotubes due to their nanoscale size. However, breaks in nanotubes, either in tension or compression, are rarely observed during specimen cutting.\textsuperscript{[152]} This fact implies that indeed nanotubes have very high strength.
Theoretical calculations of the mechanical properties of SWNTs suggest that the Young’s modulus should be close to the in-plane elastic modulus of graphite (1.06 TPa).\textsuperscript{[153]} The strength of MWNTs will be limited by the ease with which each layer slides with respect to the other. In the last few years, a number of experimental measurements of the Young’s modulus of nanotubes using TEM\textsuperscript{[128]} or AFM\textsuperscript{[154]} techniques have been reported. The average results from these experiments suggest values for Young’s modulus of individual nanotube around 1 TPa, in good agreement with the theoretical predictions.

It is known that carbon fiber reinforced composites are often stronger than steel, but much lighter. Because of this, they are used to replace metals in many applications, from parts for airplanes and space shuttles to sports utilities. Carbon nanotubes have been proposed as the ultimate carbon fibers\textsuperscript{[135]} and are considered excellent reinforcing fibers for the new generation of high performance nanocomposites.

1.3.2 Carbon Nanotube/Polymer Composites

There has been considerable effort devoted to studying nanotube/polymer composites.\textsuperscript{[152, 155-175]} Investigations of nanotube/metal composites\textsuperscript{[176]} and nanotube/ceramic composites\textsuperscript{[177]} have also been reported. It is found that the nanotubes do stiffen the composites,\textsuperscript{[163, 169, 170, 173, 177]} change the electronic structure of the polymer,\textsuperscript{[159]} improve the conductivity of the composites,\textsuperscript{[155, 169, 172, 175]} and in some cases retard the onset of thermal degradation\textsuperscript{[170, 175]} and protect the polymer from photodegradation.\textsuperscript{[158]}

The successful application of carbon nanotubes, especially as structural reinforcement in polymer composites, depends on the ability to transfer load from the matrix to the nanotubes.\textsuperscript{[164]} Effective load transfer requires strong interfacial interaction
between the matrix and the nanotubes. Without special surface treatment, some work on the carbon nanotube/polymer composites suggested strong adhesion between the matrix and the nanotubes, while others showed the opposite.

Wagner et al. reported the observation of multiple nanotube fragmentation under tensile stresses using a nanotube-containing thin polyurethane film cured under a UV lamp. Similar fragmentation tests are routinely performed to study the fiber-matrix stress transfer ability in fiber-reinforced composites. Thus, their observation proved a rather good load transfer between the nanotube and the polymer. It was suggested that the strong nanotube-polyurethane interface arose from the possible chemical bonds formed through a photo-induced “2+2” cycloaddition, a mechanism as demonstrated in C_60 photopolymerization. The same group also studied nanotube/epoxy composites and nanotube fragmentation was again observed. A recent study of carbon nanotube/carbon fiber hybrid composites suggested the presence of carbon nanotubes at the carbon fiber/epoxy interface improved the interfacial shear strength of the composites, which also supports good adhesion between the nanotube and the polymer matrix. The microscopic and spectroscopic study of carbon nanotube/poly(m-phenylenevinylene-co-2,5-dioctyloxy-p-phenylenevinylene) (PmPV) composites showed excellent wetting of the nanotubes by the polymer, again demonstrating considerable interactions between the nanotube and the polymer. The study of carbon nanotube/poly(phenylacetylenes) (CNT/PPAs) by Tang et al. was very interesting in that the nanotubes were found to be helically wrapped by the PPA chains. The wrapping process was believed to result from the strong \( \equiv C - H \cdots \pi \) hydrogen bonds formed.
between the polymer with terminal alkyne groups \( (RC ≡ C−H) \) and the nanotube that is rich in \( \pi \) electrons.

However, an earlier study of carbon nanotube/epoxy composites indicated weak interfacial bonding between the tubes and the matrix.\(^{[152]}\) Schadler and co-workers studied the load transfer in carbon nanotube/epoxy composites in both tension and compression. By monitoring the shift of the second-order Raman peak at 2700 cm\(^{-1}\) which is sensitive to the applied strain, they concluded that the load transfer in compression was effective while in tension it was poor, as demonstrated by a significant shift in compression and non-shift in tension.\(^{[161]}\)

Other work gave mixed results on this topic.\(^{[167, 171-173]}\) For example, an investigation of the fracture surface of carbon nanotube/polyhydroxyaminoether composites\(^{[171]}\) showed that, in most cases, the polymer adhered to the nanotube. However, in contrast to Wagner’s studies,\(^{[160, 166]}\) no broken carbon nanotubes were observed at the fracture surface, which indicated that the load transfer from polymer to nanotube was not sufficient to fracture the nanotubes. In studying carbon nanotube/polystyrene (CNT/PS) composites, Qian et al.\(^{[173]}\) found effective load transfer from the matrix to the nanotube by comparing the measured composite modulus with the calculated value assuming there were strong bonds between the two phases. However, when they were watching crack nucleation and propagation using \textit{in situ} TEM, the composites failed through nanotube pullout (Figure 1-9), a phenomenon that occurs when there is poor adhesion between the reinforcement and the matrix.

Based on these experimental results, computer simulations were carried out to study the nanotube/polymer interface, trying to reveal the underlying mechanisms that are
important for reinforcement of the matrix. The molecular mechanics simulations and
elasticity calculations of the interfacial characteristics of a carbon nanotube/polystyrene
composite indicated that, in the absence of atomic bonding, the interfacial load transfer
ability came from electrostatic and van der Waals interactions, deformation induced by
these interactions, and stress arising from mismatch in the coefficient of thermal
expansion. \cite{174} A molecular dynamics simulation of carbon nanotube pullout from a
polyethylene matrix \cite{180} suggested that the interfacial friction model based on a critical
force could be used to describe the entire process of nanotube pullout. In this study, 0.1
nN was predicted to be this critical force for composites with only van der Waals
interactions between the nanotube and the matrix.

In composites, a high interfacial shear stress between the fiber and the matrix
guarantees good load transfer. Typically, the introduction of mechanical interlocking and
the formation of strong bonds, such as covalent or hydrogen bonds, between the
reinforcements and the matrix will increase the interfacial shear stress. Between the two,
the second method is much more effective. It is also applicable to carbon nanotube
containing nanocomposites. In making carbon nanotube/epoxy composites, Gong et al.

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Figure 1-9. *In situ* straining of a CNT/PS composite in TEM. \cite{173}
found the addition of surfactant can increase the elastic modulus of the composites by 30% in contrast to those processed without the surfactant.\textsuperscript{[163]} There, the surfactant acted as a coupling agent. It interacted with the carbon nanotubes through the hydrophobic segment, and the hydrophilic segment simultaneously interacted with the epoxy via hydrogen bonding. Molecular dynamics simulations of the carbon nanotube/polyethylene composites with and without chemical bonding between the nanotubes and polymer showed that, in non-bonded systems, no permanent load transfer was observed; while in bonded systems, the shear strength could be enhanced by one or two orders of magnitude.\textsuperscript{[181, 182]}

As a result, in order to take real advantage of the high modulus and high strength of carbon nanotubes, chemical functionalization of carbon nanotube especially of the carbon nanotube wall, which will favor strong bond formation between the nanotube and the matrix, is necessary. As mentioned above, the carbon atoms on the walls of nanotubes are chemically stable due to the aromatic nature of the bonding. The chemistry available for modification of the nanotube wall without breaking the tubular structure is thus restricted. Recently developed chemical methods, including fluorination,\textsuperscript{[183-187]} and chemical treatment of carbon nanotubes with dichlorocarbene,\textsuperscript{[188, 189]} can chemically functionalize nanotube walls. These modified carbon nanotubes have better dispersion in solvent without aggregation, which is essential in composite processing, but do not result in significant increase in the interfacial shear strength. The oxidation of a nanotube wall by using a 3:1 mixture of concentrated H$_2$SO$_4$ (90%)/HNO$_3$ (70%)\textsuperscript{[190]} and the functionalization of the wall via electrochemical reduction by using an aryl diazonium salt\textsuperscript{[191]} have been recently reported. These techniques can tailor the surface properties of
a carbon nanotube to be favorable to form chemical bonds during nanotube composite processing. A combined computational and experimental study indicated that the local reactivity of the nanotube walls could be enhanced by the introduction of local conformational strain, such as “kinks” resulting from bending and “ridges” resulting from torsional strain. This so-called “kinky chemistry” is quite interesting because of its possibility to selectively functionalize the sidewall.

1.3.3 Motivation and Objectives

Since the discovery of carbon nanotubes, TEM has been the most frequently used technique to study their structure. When using TEM, people noticed the evolution of carbon nanotubes under the irradiation of an electron beam. Electron irradiation of carbon nanotubes can result in the formation of various atomic scale defects in the nanotube walls. Besides, electron irradiation can cause nanotubes to shrink in diameter or merge with other nanotubes through bond breaking and reformation. In other words, electron irradiation can activate the otherwise inert nanotube wall. Similar findings have been seen in simulations and experiments of the ion irradiation and plasma activation of carbon nanotubes. Specifically, simulations predict that the deposition of ions, such as CH$_3^+$, C$^+$ and Ar$^+$, at low energies of 10-80 eV/ion or higher, can induce cross-links between nanotubes arranged in bundles, neighboring shells in MWNTs, or the nanotube and the underlying substrate. A few examples are shown in Figure 1-10. Experiments of the deposition of mass-selected CF$_3^+$ ion beams deposited at 45 eV find strong evidence of chemical functionalization of the nanotube wall, which confirms the simulation predictions. In addition, both experiments and simulations of ion deposition on pure polymers show that the deposition can lead to cross-linking between polymer chains. All these findings suggest a
possible novel approach that carbon nanotube/polymer composites could be chemically functionalized to form covalent bond at the interface without first treating the tubes and/or exposing them to strong acidic or the other harsh chemical environments as described before.

![Image](image.png)

Figure 1-10. Cross-linking formed between nanotubes and adjacent shells in the case of MWNT as a result of energetic ion deposition.[200]

In this dissertation, molecular dynamics simulations are used to explore the modification of a carbon nanotube/polystyrene composite through the deposition of a beam of polyatomic ions of \( \text{C}_3\text{F}_5^+ \). One objective is to determine if polyatomic ion beam deposition is a suitable approach to induce covalent cross-links between otherwise unfunctionalized nanotubes and the polymer matrix. The second objective of this study is to examine the effects of the incident energy and the nanotube/polymer geometry. The third objective is to determine how the presence of the nanotube in the polymer affects the outcome of the polyatomic ion beam deposition relative to deposition on a pristine polymer substrate.

### 1.4 Organization of the Dissertation

The use of empirical potential energy functions to describe the interatomic interactions may not be as quantitatively accurate as \textit{ab initio} or semi-empirical methods
due to the approximations introduced and parameter fitting. But, they have obvious advantages over semi-empirical and \textit{ab initio} methods, especially when large systems and long timescales are desired. In this dissertation, the reactive empirical bond order (REBO) potential for carbon-based covalent systems is used to describe the short-range covalent bonding. In order to test the accuracy of the REBO potential, in Chapter 2, the simulation results using the REBO potential and a semi-empirical tight-binding scheme are first compared. Since in experiments, both the cluster beam deposition and polyatomic ion beam deposition usually occur at room temperature, a proper temperature control algorithm should be employed in the simulations. Chapter 3 thus describes several temperature control methods. Their efficiency specifically in dealing with the deposition systems is presented. Chapter 4 reports the MD simulation results for thin film nucleation via organic cluster beam depositions. Chapter 5 presents the MD simulations of chemical modification of carbon nanotube/polymer composites through polyatomic ion beam deposition. Finally, the overall conclusions of this work are given in Chapter 6.
CHAPTER 2
COMPARISON OF O(N)/NOTB AND REBO POTENTIAL MOLECULAR DYNAMICS SIMULATIONS

In modeling a many-body system, it is essential to find an appropriate method to calculate the interatomic energies and forces. These interactions can be considered using \textit{ab initio} calculations, semi-empirical methods, or empirical function expressions. In \textit{ab initio} calculations, all the electrons are treated explicitly and quantum mechanically. Thus, they give the most exact results but are the most computationally demanding. \textit{Ab initio} calculations are usually limited to modeling small systems containing several hundred atoms. Semi-empirical methods explicitly consider the contribution of some of the electrons (generally some of or all of the valence electrons), which is usually denoted as the band structure energy; the contributions of the other electrons are taken into account via various mathematical expressions fitted to experimental data or first principle (\textit{ab initio}) results. Because of their semi-empirical character, these methods usually give fairly accurate results while the computational workload is comparatively small, and relatively large-scale simulations (~ 5,000 atoms) are possible. Empirical potential functions are further simplified mathematical expressions that do not explicitly consider any electron contributions, but model the interatomic forces from the interactions of electrons and nuclei by appropriate parameter fitting reasonably well.\cite{205} Due to their great computational efficiency, empirical potential functions have obvious advantages for large systems (more than several thousand atoms) and long simulation times, although
the results may be subject to errors that can arise from the assumed functional forms and parameter fitting.\textsuperscript{[205]}

The order-N nonorthogonal tight-binding (O(N)/NOTB) method of Wu and Jayanthi\textsuperscript{[206]} is a semi-empirical approach that explicitly incorporates the band structure energy. This scheme has been successfully applied to study a wide range of problems associated with nanostructures, including the initial stage of growth of Si/Si(001),\textsuperscript{[207]} carbon nanotubes,\textsuperscript{[208]} and Si nanoclusters.\textsuperscript{[209]} The reactive empirical bond-order (REBO) potential is a refinement of the Abell-Tersoff potential and was parameterized by Brenner et al. initially for hydrocarbons.\textsuperscript{[210, 211]} Due to its flexibility to allow bond breaking and reforming with appropriate changes in atomic hybridization, the REBO potential gives structural predictions for diamond surface reconstruction consistent with \textit{ab initio} studies.\textsuperscript{[212, 213]} It has found extensive uses in modeling other structures and processes as well, such as chemical processes in reactive hydrocarbon systems,\textsuperscript{[95, 214-217]} properties of fullerenes and carbon nanotubes,\textsuperscript{[145, 218-225]} and mechanical processes associated with indentation, friction and compression.\textsuperscript{[225-230]} An extended REBO potential for Si-Si, Si-C and Si-H interactions has also been reported to reproduce \textit{ab initio} predictions and/or experimental results of the equilibrium structures and binding energies for C-Si-H systems reasonably well.\textsuperscript{[231-234]} Despite all these successful applications, as is the case with most empirical potentials, there are cases where the results from the REBO potential lack the quantitative accuracy even while the qualitative predictions are correct.\textsuperscript{[235-237]}

In this work, simulation results from the O(N)/NOTB method and the REBO potential are compared and contrasted. The process investigated is the collision of hydrocarbon clusters on diamond surfaces. This process usually occurs on the time scale
of a few picoseconds (ps) if the collision happens at hyperthermal (1-500 eV) or higher energies. Molecular dynamics (MD) simulations are thus well suited to study this process. For convenience, the MD simulation using the REBO potential is denoted as empirical MD (EMD), and the one using the O(N)/NOTB method is O(N)/NOTB-MD. The purpose of this work is to check both the qualitative and quantitative predictions from the REBO potential against the results from the O(N)/NOTB method, and thus to obtain a better knowledge of the reliability of the REBO potential.

2.1 Order-N Nonorthogonal Tight-Binding (O(N)/NOTB) Method

In the semi-empirical tight-binding scheme, the total energy of a system can be written as:

\[ U_{tot} = U_{bs} + U_{rep} \]  

(2-1)

where \( U_{bs} \) is the band structure energy that considers the electronic contributions to the atomic forces. \( U_{rep} \) is a pair wise repulsive term, which considers the effects of the overlap interactions and the possible charge transfer that are neglected in \( U_{bs} \). \( U_{rep} \) can be expressed as a sum of suitable empirical two-body potentials \( \Phi(r_{ij}) \):

\[ U_{rep} = \sum_i \sum_j \Phi(r_{ij}) \]  

(2-2)

where \( r_{ij} \) is the distance between the \( i \)th and \( j \)th atom. \( \Phi(r_{ij}) \) is obtained by parameter fitting.

In the O(N)/NOTB approach of Jayanthi et al.,\(^{206}\) the band structure energy is expressed as:

\[ U_{bs} = 2 \sum_{\lambda(occ)} E_\lambda = 2 \sum_{\lambda,\mu} \rho_{\lambda\mu} H_{\beta\gamma,\lambda\mu} \]  

(2-3)
where the multiplier 2 takes account of the electron spin, \( E_i \) is the electronic eigenenergy of the system, \( \rho_{\alpha\beta} \) is the density matrix, and \( H_{\beta\alpha} \) is the Hamiltonian matrix element. Therefore, the electronic contribution to the force acting on the \( i \)th atom can be evaluated as:

\[
F_{i,el} = -\frac{\partial U_{ba}}{\partial r_i} = -2\sum_{\alpha,\beta} \left\{ \rho_{\alpha\beta} \frac{\partial H_{\beta\alpha}}{\partial r_i} - \tau_{\alpha\beta} \frac{\partial S_{\beta\alpha}}{\partial r_i} \right\}
\]  

(2-4)

where \( \tau_{\alpha\beta} \) is the energy density matrix, and \( S_{\beta\alpha} \) is the overlap matrix element. The total force acting on a given atom \( i \), is thus given by \( F_i = F_{i,el} = \frac{\partial U_{rep}}{\partial r_i} \).

The application of the tight-binding method to study a system containing \( 10^3-10^6 \) atoms is usually restricted by the \( N^3 \) scaling of the calculation of the total energy and atomic forces. Using the property that \( \rho_{\alpha\beta}(r_g) \to 0 \) and \( \tau_{\alpha\beta}(r_g) \to 0 \) as \( r_g \to \infty \), the summations in Equations (2-3) and (2-4) can be truncated to include only terms within a sphere of radius \( r_{cut} \) if it can be established that \( \rho_{\alpha\beta}(r_g) \approx 0 \) and \( \tau_{\alpha\beta}(r_g) \approx 0 \) for \( r_g > r_{cut} \). With the truncation, the calculation of the total energy and the atomic forces will depend linearly on the size of the system. That is, it becomes an order-N (O(N)) scaling procedure. Therefore, this O(N)/NOTB scheme can be efficiently applied to a system that contains more than 1000 atoms.

In this O(N)/NOTB approach, the parameters characterizing the C-H interactions are fit so that the predicted bond lengths and bond angles for \( \text{C}_2\text{H}_2 \), \( \text{CH}_4 \), \( \text{C}_2\text{H}_4 \), and \( \text{C}_2\text{H}_6 \) are in good agreement with experimental results. The MD simulations using the O(N)/NOTB method were performed by our collaborators in the University of Louisville.
2.2 Reactive Empirical Bond-Order (REBO) Potential

The general analytic bond-order potential energy formalism was originally introduced by Abell,\cite{239} in which he showed that the chemical binding energy $U_b$ can be simply expressed as a sum over nearest neighbors:

$$U_b = \sum_i \sum_{j(\neq i)} [V_R(r_{ij}) - b_{ij}V_A(r_{ij})]$$  \hspace{1cm} (2-5)

The functions $V_R(r)$ and $V_A(r)$ are pair-additive terms that describe the interatomic repulsions and attractions, respectively. The term $b_{ij}$ is a bond-order term between atoms $i$ and $j$. A practical implementation of Abell’s bond-order formalism was first developed by Tersoff for group IV elements.\cite{240, 241} By introducing analytic parameterized forms for the bond order term, the Tersoff potential can accurately treat silicon, germanium and their alloys, but is less reliable for carbon.\cite{213}

Carbon is a very unique element in that it has a variety of different types of C-C bonding with very different energies and bond lengths, which results in a large variety of polymorphic forms, such as diamond, graphite, fullerene, and various amorphous phases.\cite{242} The Tersoff potential does not distinguish the chemical character of the bond,\cite{213} therefore, it cannot describe processes involving a change of bonding characters, such as surface reconstruction and chemical reactions, very well. In 1990, the reactive empirical bond-order (REBO) potential for describing solid-state carbon and hydrocarbon molecules was reported by Brenner.\cite{210} In this potential, nonlocal terms, which properly account for the chemical bonding changes based on the change of neighboring atoms, are added to the Tersoff potential. Consequently, the REBO potential allows for bond formation and breaking with appropriate changes in atomic hybridization, which is crucial for realistic treatment of such processes as chemical
reactions. Thanks to the development of the REBO potential, it is now possible to model simple organic chemical reactions within an empirical scheme. However, in the first generation REBO potential, the terms describing the pair interactions in Equation (2-5) were found to be too restrictive to simultaneously fit equilibrium distances, bond energies, and force constants for carbon-carbon bonds. What is more, both terms go to finite values as the distance between atoms decreases, which limit the possibility of modeling processes such as energetic atomic collisions. Therefore, the second generation REBO potential, using improved analytic functions for interatomic interactions and an expanded fitting database, was developed.\cite{211} The forces associated with rotation about dihedral angles for carbon-carbon double bonds, as well as angular interactions associated with hydrogen centers, have also been included. In this study, the second generation REBO potential\cite{211} is used.

The analytic terms describing the pair interactions in Equation (2-5) in the second generation REBO potential are written as:

\begin{equation}
V_r(r) = f^c(r)(1 + \frac{Q}{r})Ae^{-\alpha r} \tag{2-6}
\end{equation}

\begin{equation}
V_a(r) = f^a(r)\sum_n B_n e^{-\beta_n r} \tag{2-7}
\end{equation}

The function for the repulsive interactions (Equation (2-6)) goes to infinity as the interatomic distance \(r\) approaches zero, and the attractive term (Equation (2-7)) has sufficient flexibility to simultaneously fit the bond properties. The variables \(Q, A, \alpha, B\) and \(\beta\) are all parameters that are fit to experimental or \textit{ab initio} data for both hydrocarbon molecules and solid-state carbon, and are adjusted using a standard fitting routine. The
function $f^\pi(r)$ limits the range of the covalent interactions. For carbon, the value of $f^\pi(r)$ will be one for nearest neighbors and zero for all other interatomic distances.

The bond-order term in the second generation REBO potential is written as the sum of terms:

$$b_{ij} = \frac{1}{2} [b_{ij}^{\sigma-\pi} + b_{ji}^{\sigma-\pi}] + b_{ij}^\pi$$ \hspace{1cm} (2-8)

Values for the functions $b_{ij}^{\sigma-\pi}$ and $b_{ji}^{\sigma-\pi}$ depend on the local coordination and bond angles for atoms $i$ and $j$. The dependence on bond angles is necessary to accurately model elastic properties and defect energies. The function $b_{ij}^\pi$ is further expressed as a sum of two terms:

$$b_{ij}^\pi = \prod_{ij}^{RC} + b_{ij}^{DH}$$ \hspace{1cm} (2-9)

where the value of the first term depends on whether a bond between atoms $i$ and $j$ has radical character and is part of a conjugated system. The value of the second term depends on the dihedral angle for carbon-carbon double bonds.

Within a single expression, as introduced by Abell (Equation (2-5)), the revised REBO potential accurately reflects the bond energies, bond lengths and force constants for carbon-carbon bonds. It has produced an improved fit to radical energies, conjugated $\pi$ bonding properties, and diamond surface properties. It also gives a reasonable description of diamond, graphitic and hybrid diamond-graphitic structures.\textsuperscript{[243]}

The REBO potential describes short-range covalent interactions. In order to take into account long-range van der Waals molecular interactions, Lennard-Jones (LJ) 6-12 potential can be coupled with the REBO potential. Thus, the combined expression to calculate the binding energy between atoms $i$ and $j$ is:
\[ U = \sum_i \sum_{j \neq i} c_{ij} V_{ij} - b_{ij} V_{ij} + V_{vdw}(r_{ij}) \]  

where \( V_{vdw} \) is the contribution from the van der Waals interactions, which, in turn, can be expressed as:

\[ V_{vdw}(r) = 4\varepsilon \left[ \left( \frac{\sigma}{r} \right)^{12} - \left( \frac{\sigma}{r} \right)^{6} \right] \]

where \( \varepsilon \) and \( \sigma \) are Lennard-Jones parameters. The LJ potential is turned on only when the REBO potential has gone to zero (at about 2.0 Å for C-C interactions, 1.8 Å for C-H interactions, and 1.7 Å for H-H interactions).

### 2.3 Testing Systems

The energetic cluster-beam investigated in this study contains two molecular ethylene clusters. Each cluster is formed by arranging eight ethylene molecules on a three-dimensional grid in which three-dimensional periodic boundary conditions are applied. Therefore there are 48 atoms per cluster and 16 of them are carbon atoms. First, the cluster molecules are equilibrated at 500 K. When the cluster has fully relaxed, it is quenched to 5 K to minimize the internal cluster kinetic energy. The clusters are then combined together to form a beam. Before deposition, the whole beam is placed about 4 Å above the surface. The two clusters are deposited along the surface normal at an incident energy of 25 eV/molecule, which corresponds to a velocity of 13.1 km/s. The distance between the two clusters in the beam is about 4 Å. Therefore, the two clusters impact the substrate in a consecutive manner, with the second cluster hitting the surface 30.5 fs after the first.

Eight hydrogen-terminated diamond (111) substrates of various sizes are used in this study, as indicated in Table 2-1. The largest substrate contains over ten times as
many atoms as the smallest one. These various substrates are chosen in order to compare the computational capability of the two methods. Prior to cluster deposition, all the substrates are equilibrated at 500 K and then cooled to 300 K, which is the temperature that is maintained throughout the whole deposition process. Periodic boundaries are applied within the impact plane.

<table>
<thead>
<tr>
<th># of atoms in the substrate</th>
<th>1260</th>
<th>2352</th>
<th>3136</th>
<th>4480</th>
<th>5824</th>
<th>7168</th>
<th>9216</th>
<th>16128</th>
</tr>
</thead>
<tbody>
<tr>
<td>Impact area (Å²)</td>
<td>455.8</td>
<td>615.1</td>
<td>1166.2</td>
<td>1166.2</td>
<td>1166.2</td>
<td>1166.2</td>
<td>1509.3</td>
<td>2672.9</td>
</tr>
<tr>
<td>Thickness (Å)</td>
<td>13.0</td>
<td>13.0</td>
<td>13.0</td>
<td>19.1</td>
<td>25.3</td>
<td>31.5</td>
<td>31.5</td>
<td>31.5</td>
</tr>
</tbody>
</table>

In order to mimic the heat dissipation of a real substrate and maintain the system temperature at 300 K during the deposition, the Berendsen thermostat\(^{245}\) is used in both the EMD and O(N)/NOTB-MD simulations. Approximately 3-5 rows of atoms at the edges and the carbon atoms of the lower half part of the whole surface slab are thermostat atoms. Therefore, the thermostat atoms form a bathtub-like shape, helping to control the system temperature. The bottom layer of hydrogen atoms for each surface is held rigid to maintain the substrate structure during the deposition. All the other atoms in the substrate and in the cluster beam evolve without any additional constraints.

During the deposition, the majority of the incident energy of the cluster molecules is transformed into excess surface kinetic energy. In the case of the larger substrates, this excess surface kinetic energy is quickly dissipated by the thermostat atoms and does not bounce back to interfere with the chemical interactions taking place at the surface. However, in the smaller substrates, this dissipation does not take place quickly enough and the excess energy is reflected back from the boundary of the substrate (this occurs whether or not the bottom layer is held rigid). This reflection of energy occurs to somewhat different degrees in the EMD and O(N)/NOTB-MD simulations (see the
discussion below). As the point of this study is the comparison of the predictions of these two methods, this reflection of energy does not detract from our objective as long as the results of the deposition on a same surface are compared.

For statistical purposes, several trajectories are performed for each surface and the results are averaged. In the case of the O(N)/NOTB-MD simulations, three trajectories are run for each of the three smallest surfaces (1260, 2352 and 3136 atoms/surface). In the case of the EMD simulations, the same three trajectories are run on the same three surfaces so that the EMD and O(N)/NOTB-MD results may be compared. In addition, since the EMD method is much faster than the O(N)/NOTB-MD method and more trajectories lead to better statistical representation of the results, ten trajectories total were run for each of the eight surfaces considered.

The time step is 0.2 fs. The simulations run for at least 1 ps with the clusters impacting on the surface during the first 0.16 ps and the film relaxing thereafter. Each O(N)/NOTB-MD simulation typically required 12 nodes of an IBM RS/6000 SP2 supercomputer (with 48 CPUs) and ran for about 4 days, while each EMD simulation typically ran for a few hours (the largest simulations ran about one day) on a Compaq Alpha64 workstation.

2.4 Results and Discussion

When the molecular clusters come into contact with the surface, numerous chemical reactions occur among the cluster molecules and between the cluster and the substrate, resulting in hydrocarbon thin film nucleation and growth. Both the O(N)/NOTB-MD and EMD methods predict that when the clusters impact the substrate with the short time lag of 30.5 fs, many more of the carbon atoms in the film are from the first incident cluster. Furthermore, both methods predict that within a given cluster, more
atoms from the lower half of the cluster (closest to the substrate) remain behind to form the film.

The atoms that are identified as being part of the resultant thin film include substrate atoms that are displaced from their original positions and pushed up into the film while still maintaining a connection to the substrate. In addition, some atoms from the cluster may penetrate deeply into the substrate beyond the range of the film. Although these atoms are included in the calculation of the number of atoms from the cluster that adhere to the surface, they are not considered when the structure of the film is examined.

The percentage of carbon atoms in clusters adhering to the substrate predicted by O(N)/NOTB-MD and EMD for surfaces with 1260, 2352 and 3136 atoms/surface is shown in Figure 2-1. The O(N)/NOTB-MD method predicts a higher percentage of adhesion (approximately 20-30% more) than the EMD does for the same surface. In the EMD simulations, when the distance between two atoms is less than 1.73 Å, those two atoms are considered to have formed a bond. In the O(N)/NOTB-MD approach, when the number of electrons in the bond region is greater than or equal to 0.04, a bond is considered to be formed.[246] When the distance approach is compared to the electron counting approach for the same set of O(N)/NOTB-MD results, the electron counting approach is found to yield results consistent with those of the distance approach in that there is no bond determined on the basis of the electron counting approach with a bond length greater than 1.73 Å. Hence, the difference in the percentage of adhesion between the two approaches is due to differences inherent to the empirical and tight-binding methods themselves.
Figure 2-1. The percentage of incident carbon atoms that adhere to the substrate (averaged over three trajectories) versus the size of the substrate. The total number of atoms in each substrate is used to quantify the substrate size. The predictions from both O(N)/NOTB-MD and EMD approaches are shown.

To better characterize this difference, the potential energy curves of three reactions are considered from static calculations using the REBO and O(N)/NOTB-MD potentials with a time step of 0.1 fs. The results are plotted in Figure 2-2. In the figure, the values of $(0 - PE)$, where $PE$ is the calculated potential energy, are plotted for easy comparison.

The first case is the movement of two ethylene molecules towards each other along a path that is horizontal to the carbon-carbon double bonds, shown in Figure 2-2(a). The second case is the movement of two ethylene molecules towards each other along a path that is perpendicular to the double bonds, shown in Figure 2-2(b). The final case is the movement of two molecular clusters of ethylene (where each cluster contains eight molecules) towards each other, shown in Figure 2-2(c).

If one ignores the fine details, one will be struck by the similarities in the overall shapes of the energy curves obtained by the two approaches. This is particularly true in
Figure 2-2. Potential energy curves calculated with O(N)/NOTB-MD and EMD methods for the three reactions: (a) the movement of two ethylene molecules towards each other in a direction horizontal to the double bonds; (b) the movement of two ethylene molecules towards each other in a direction perpendicular to the double bonds; and (c) the movement of two ethylene clusters towards one another.
the third case where the energy curves between two molecular clusters of ethylene obtained by the two methods have remarkably similar shapes. However, there are also crucial differences between the energy curves obtained by the two methods. From Figure 2-2, it can be seen that, in all three cases, there are regions of separation close to the C-C bond length where the energy obtained by the NOTB Hamiltonian is less than that obtained by the REBO potential (see the insert in Figure 2-2(c)). The similarities of the energy curves obtained by the two methods are indications that the REBO potential has indeed captured the general characters of carbon-based chemistry. But the differences show that the NOTB Hamiltonian predicts a more attractive interaction and in general a lower potential barrier in the region of bond-breaking and bond formation than the REBO potential. Therefore, the REBO potential may not be sufficiently flexible to describe all the relevant processes of bond breaking and bond forming in cluster-beam deposition, thus leading to a lower percentage of adhesion.

As shown in Figure 2-1, when the substrate size changes, both the O(N)/NOTB-MD and EMD simulations predict that the adhesion percentage is approximately constant. When 10 trajectories of EMD simulations are averaged for each of the eight substrates, the results also display little variation in the adhesion percentage with the changing substrate (see Figure 2-3). The factors contributing to the deviation in the adhesion percentage include changes in the precise impact sites on the surfaces, thermal fluctuations, and changes in the elastic collisions among the cluster molecules, in addition to the effect of the reflected energy from the boundary in the case of the smaller substrates.
Figure 2-3. The percentage of incident carbon atoms that adhere to the substrate (averaged over ten trajectories) versus the size of the substrate. The total number of atoms in each substrate is used to quantify the substrate size. The results are predicted by the EMD approach.

Figure 2-4. Snapshots of the thin film formed on the hydrogen terminated diamond (111) surface containing 3136 atoms. The black spheres are carbon atoms in the cluster beam, the gray spheres are substrate carbon atoms, and the white spheres are hydrogen atoms. (a) O(N)/NOTB-MD result; (b) EMD result.

Typical snapshots of the nucleated thin films predicted by the O(N)/NOTB-MD and EMD simulations are given in Figures 2-4(a) and (b), respectively. It is clear that the film is denser and spreads more widely in the O(N)/NOTB-MD simulations, while in the EMD simulations the film is more chain-like. These comparisons are made in a more quantitative manner by determining the coordination of the carbon atoms in the film and
the manner in which the carbon atoms in the film are bonded to the other film carbon atoms (hereafter referred to as carbon connectivity).

Table 2-2 summarizes the coordination of the carbon atoms in the film predicted from the O(N)/NOTB-MD and EMD simulations for surfaces with 1260, 2352 and 3136 atoms/surface (only the averaged values are reported). Compared to the EMD results, the film with a higher percentage of sp\(^3\)-hybridized carbon while less sp\(^2\)-hybridized carbon and no sp-hybridized carbon is predicted from the O(N)/NOTB-MD method. In the EMD simulations, the hybridization of the carbon in the film ranges from sp to sp\(^3\). In other words, the O(N)/NOTB-MD simulations predict the formation of a highly saturated thin-film structure while the EMD simulations predict the formation of a more unsaturated structure. Table 2-3 summarizes the averaged hybridization of the carbon atoms in the films formed on all eight surfaces predicted from the EMD simulations.

<table>
<thead>
<tr>
<th># of atoms in the substrate</th>
<th>1260</th>
<th>2352</th>
<th>3136</th>
</tr>
</thead>
<tbody>
<tr>
<td>sp (^3)</td>
<td>78</td>
<td>84</td>
<td>87</td>
</tr>
<tr>
<td>sp (^2)</td>
<td>22</td>
<td>16</td>
<td>/</td>
</tr>
<tr>
<td>sp</td>
<td>/</td>
<td>/</td>
<td>/</td>
</tr>
</tbody>
</table>

<table>
<thead>
<tr>
<th># of atoms in the substrate</th>
<th>1260</th>
<th>2352</th>
<th>3136</th>
<th>4480</th>
<th>5824</th>
<th>7168</th>
<th>9216</th>
<th>16128</th>
</tr>
</thead>
<tbody>
<tr>
<td>sp (^3)</td>
<td>54</td>
<td>30</td>
<td>40</td>
<td>27</td>
<td>27</td>
<td>35</td>
<td>39</td>
<td>45</td>
</tr>
<tr>
<td>sp (^2)</td>
<td>29</td>
<td>58</td>
<td>53</td>
<td>70</td>
<td>53</td>
<td>45</td>
<td>46</td>
<td>44</td>
</tr>
<tr>
<td>sp</td>
<td>/</td>
<td>/</td>
<td>/</td>
<td>/</td>
<td>/</td>
<td>/</td>
<td>/</td>
<td>/</td>
</tr>
</tbody>
</table>

A close examination of Tables 2-2 and 2-3 reveals a role reversal in the percentages of carbon atoms with sp\(^2\) and sp\(^3\) bonding in the film between the 1260 and 2352...
atoms/surfaces for the EMD simulations while no such reversal is seen for the O(N)/NOTB-MD simulations. This observation can be understood as follows. For EMD simulations, the 1260-atom surface is just too small to allow for a quick dissipation of any substantial amount of the excess surface kinetic energy. Therefore, the reflected excess energy quickly breaks up the remnant sp$^2$-bonded structures in the incoming clusters. This action, in turn, promotes more chemical reactions at the surface, leading to a larger percentage of sp$^3$-bonded carbon atoms. The 2352-atom surface, on the other hand, is large enough to dissipate some of the excess energy such that the reflected energy is not sufficient to break up the remnant stable sp$^2$-bonded structures in the incoming clusters, but still enough to break up some of the newly formed sp$^3$-bonded structures at the surface. This facilitates the formation of additional sp$^2$-bonded structures. As the size of the surface increases further, the effect of the reflected energy decreases more. This trend can be clearly seen from the results shown in Table 2-3, which suggests that the effect of the reflected energy has almost disappeared for the 7168-atom surface in the case of EMD simulations.

For the O(N)/NOTB-MD simulations, because the NOTB Hamiltonian is more flexible, the excess surface kinetic energy dissipates more quickly than the corresponding situation in the EMD simulations. Hence, even for the 1260-atom surface, some of the excess energy has already been dissipated to the extent that the reflected energy is only sufficient to break up the sp$^3$ structures formed as a result of chemical reactions at the surface. Therefore, the differences in the distribution of the percentages of sp$^2$- and sp$^3$-bonded structures between the two cases can also be attributed to the rigidity of the REBO potential vs. the flexibility of the NOTB Hamiltonian.
The carbon connectivity within the nucleated films predicted by the O(N)/NOTB-MD and EMD simulations for surfaces with 1260, 2352 and 3136 atoms/surface is shown in Table 2-4 (only the averages are given). In the table, C1 stands for the percentage of carbon atoms connected to one other carbon atom, C2 stands for the percentage of carbon atoms connected to two other carbon atoms, and so on. Therefore, the summation of C1 and C2 indicates the percentage of carbon atoms bonded in a linear structure, while C3 and C4 indicate the percentage of carbon atoms connected in the branched and networked structure, respectively. For each surface, the carbon connectivity within the film predicted by O(N)/NOTB-MD is different from what is predicted by the EMD simulations. In general, O(N)/NOTB-MD predicts more branched or networked structures and less linear structure than the EMD simulations. When both the coordination and the carbon connectivity of the film carbon atoms are considered, the O(N)/NOTB-MD method is found to predict the formation of a more diamond-like thin film while the EMD simulations predict a more linear unsaturated polymer-like thin film.

<table>
<thead>
<tr>
<th># of atoms in the surface</th>
<th>1260</th>
<th>2352</th>
<th>3136</th>
</tr>
</thead>
<tbody>
<tr>
<td>O(N)/NOTB-MD</td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>C1</td>
<td>30</td>
<td>29</td>
<td>42</td>
</tr>
<tr>
<td>C2</td>
<td>46</td>
<td>37</td>
<td>29</td>
</tr>
<tr>
<td>C3</td>
<td>22</td>
<td>34</td>
<td>25</td>
</tr>
<tr>
<td>C4</td>
<td>2</td>
<td>/</td>
<td>4</td>
</tr>
<tr>
<td>EMD</td>
<td></td>
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**2.5 Conclusions**

The simulation results for ethylene molecular cluster deposition predicted by O(N)/NOTB-MD and EMD using REBO potential are compared. The results of these two methods do not agree perfectly well with each other, especially the quantitative
predictions. For instance, the structures of the resultant thin films are significantly different from one another. Nevertheless, the qualitative predictions are comparable. For example, both methods predict thin-film nucleation through rapid chemical reactions and most of the atoms in the nucleated thin film are from those incident clusters closest to the substrate.

This comparison study shows that the REBO potential has indeed captured the general characters of carbon-based chemistry. However, the differences in the predictions from the two methods indicate that as compared to the NOTB Hamiltonian, the REBO potential is more rigid, and hence may not be sufficiently flexible to describe all the relevant processes of bond breaking and bond forming. A key point is that NOTB Hamiltonian predicts a more attractive interaction and in general a lower repulsive barrier than the REBO potential. These results and conclusions appear in Reference [247].

In modeling thin film deposition of amorphous carbons, Jäger and Albe observed that the REBO potential predicted a structure with lower sp³ content than the experimental results. But when the cutoff distance (2 Å for C-C interactions in REBO potential) was slightly increased, a structure with realistic density and sp³ content could be produced. The study of H-atom association with diamond surfaces by Hase and co-workers also pointed out that, the major reason of the quantitative inaccuracy of REBO potential was the potential’s shorter range. But, within the REBO potential cutoff, the predicted results agree very well with the ab initio calculations. Therefore, in the case of energetic collisions, if the incident energy is high enough to bring the particles into close contact (well within the potential cutoff) prior to any reaction, the predictions from the REBO potential should be reliable.
In this dissertation, the incident energies used in the following simulations of organic molecular cluster beam deposition and polyatomic ion beam depositions are much higher. The REBO potential’s shorter range is thus not of significant concern. In addition, the systems considered contain more than 10,000 atoms. Although \( O(N)/\text{NOTB-MD} \) is a more accurate method, it is more computationally expensive than the EMD method for a surface of a given size. It is practically impossible for a simulation of a system that consists of more than 10,000 atoms by using the NOTB method within a reasonable period of time. Empirical potential is necessary to study the collective phenomena of many atoms or for long times at an atomic scale. Therefore, the second generation REBO potential is used in the following simulations to consider the short-ranged interatomic interactions, and the predictions are believed to be at least qualitatively accurate.
CHAPTER 3
TEMPERATURE CONTROL METHODS

Energetic particle deposition is a process that involves a flux of energy into or out of a system. In addition, complex and rapid chemical reactions may occur between the incident particles and the substrate atoms, which lead to big changes in the system energy. These energy changes are reflected in variations in system temperature. Experimentally, particle deposition is usually carried out at specific temperatures to obtain the desired properties. Furthermore, macroscopic substrates dissipate the excess energy from the deposition process through, for example, lattice vibrations through the extended lattice.

To model such processes atomistically, molecular dynamics simulations can be performed in a canonical ensemble, where the number of particles, temperature, and volume are held constant. Periodic boundary conditions are often used in these simulations to mimic an infinite or semi-infinite system with just a few thousand atoms and to keep the volume constant. Sometimes, certain amounts of boundary atoms need to be fixed to keep the structure of the simulation system from reconstructing. However, these boundary conditions can result in the nonphysical reflection of energy from the boundary, which will then produce spurious effects on the simulation results. Therefore, the simulations make use of methods that can allow some atoms to effectively absorb all the extra energy pumped into a system (including any reflected energy) and thus successfully control the system temperature in a physically reasonable manner. Simulations that implement these methods are called constant temperature simulations.\textsuperscript{[2]}

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Temperature is a thermodynamic quantity. For a system containing $N$ particles, the temperature can be related to the average kinetic energy ($\langle K \rangle$) of the system through the principle of equipartition of energy, which states that every degree of freedom has an average energy of $\frac{k_B T}{2}$ associated with it.\[248\] That is,

$$\langle K \rangle = \frac{1}{2} \sum_i m v_i^2 = \frac{N_f k_B T}{2}$$

(3-1)

where $N_f$ is the number of degrees of freedom, $k_B$ is the Boltzmann constant, and $T$ is the thermodynamic temperature. Similarly, the instantaneous kinetic temperature can be defined as

$$T_{\text{inv}} = \frac{2K}{N_f k_B}$$

(3-2)

The average of the instantaneous kinetic temperature is equal to the thermodynamic temperature.

Since the temperature is related to the kinetic energy, in order to control the temperature, the velocities of the particles in the simulation system must be adjusted. One way to do this is to directly rescale the velocity of each particle, as shown in Equation (3-3):

$$\left( \frac{v_{\text{new}}}{v_{\text{old}}} \right)^2 = \frac{T}{T_{\text{inv}}}$$

(3-3)

where $v_{\text{new}}$ is the rescaled velocity, and $v_{\text{old}}$ is the velocity before the rescaling.

Although this method, called the velocity rescaling method, is very simple and adds (or subtracts) energy to (or from) the system efficiently, it is important to recognize that it actually keeps the kinetic energy constant, which is not equivalent to the condition of
constant temperature. At thermal equilibrium, both kinetic energy (instantaneous kinetic temperature) and potential energy fluctuate. Therefore, the direct velocity rescaling method is somewhat coarse and far removed from the way energy is actually dissipated.[2]

Better and more realistic constant temperature schemes have been proposed. Among these schemes, the generalized Langevin equation (GLEQ) approach,[249] Berendsen method,[245] and Nosé-Hoover thermostat[250-253] are the most widely used. In all these schemes, the velocities of the particles are adjusted to maintain the system temperature at a constant value.

Simulation systems generally consist of an impact zone, where atoms move only in response to normal Newtonian dynamics, that is embedded in a thermostat zone, where the velocities of the atoms are modified using the temperature control schemes. The thermostat zone not only acts as a heat reservoir but is also used as a cushion to absorb any reflected energy waves.

In this study, both the GLEQ approach and the Berendsen method are used in the thermostat zone in constant temperature MD simulations of cluster deposition on surfaces. A variation of the regular GLEQ approach and a combined thermostat of the GLEQ and Berendsen methods are also tested. The goal of this work is to determine which thermostat method is the best for use in MD simulations of energetic particle deposition on surfaces to realistically control the temperature and reduce the amplitude of reflected waves from the boundaries of the simulation unit cell edges.

3.1 Methods of Interest

3.1.1 Generalized Langevin Equation (GLEQ) Approach

The generalized Langevin equation (GLEQ) approach proposed by Adelman and Doll[249] is developed from generalized Brownian motion theory. It models solid lattices
at finite temperature using the methods of stochastic theory. In this approach, the molecular system of interest can be thought of as being embedded in a “solvent” that imposes the desired temperature; the molecules are regarded as solutes. The solvent affects the solute through the addition of two terms to the normal Newtonian equation of motion: one is the frictional force and the other is the random force.

The frictional force takes account of the frictional drag from the solvent as the solute moves. Since friction opposes motion, this force is usually taken to be proportional to the velocity of the particle but of opposite sign:

\[ F_{\text{friction}}(t) = -\beta \dot{v}(t) \]  

(3-4)

The proportionality constant, \( \beta \), is called the friction constant. Using the Debye solid model, \( \beta \) can be simply expressed as

\[ \beta = \frac{1}{6} \pi \omega_D \]  

(3-5)

where \( \omega_D \) is the Debye frequency. The Debye frequency is related to the experimentally measurable Debye temperature \( T_D \) by

\[ \omega_D = \frac{k_B T_D}{\hbar} \]  

(3-6)

The random collisions between the solute and the solvent is controlled by the random force, \( \mathbf{R}(t) \). This random force is assumed to have no relation to the particle velocity and position, and is often taken to follow a Gaussian distribution with a zero mean and a variance \( \sigma^2 \) given by

\[ \sigma^2 = \frac{2m \beta k_B T}{\Delta t} \]  

(3-7)
where $T$ is the desired temperature, and $\Delta t$ is the time step. This random force is balanced with the frictional force to maintain the temperature.\[217\]

Therefore, the equation of motion for a “solute” particle is

$$ma(t) = F(t) - \beta v(t) + R(t) \tag{3-8}$$

which is called the Langevin equation of motion. Following the Langevin equation of motion instead of Newton’s second law, the velocity of the system particle is thus gradually modified to bring the instantaneous kinetic temperature closer to the desired temperature. The GLEQ approach is a proportional control algorithm that changes the temperature exponentially as a function of $\beta$ and the initial conditions.\[254\] This approach often gives a good representation of energy relaxation in surface scattering simulations.\[249\] It also satisfactorily describes heat dissipation at boundaries and has been found to be best suited for thin film deposition processes.\[254\]

In practice, some other expressions for the frictional force and random force can be selected to better describe the physical condition of the system.\[254\] However, the expressions mentioned above are the simplest, and hence, the most computationally efficient. In simulations where the thermostat zone is far away form the zone of interest, the results using these expressions have proven to be reliable.\[217\] In this study, the GLEQ approach using the expressions described above for the frictional force and random force is chosen to control the simulation temperature.

### 3.1.2 Berendsen Method

Before the introduction of the Berendsen method, it is worthwhile to first mention the Andersen method. The Anderson method of temperature control was proposed in 1980.\[255\] This method can be thought of as a system that is coupled to a thermal bath.
held at the desired temperature. The coupling is simulated by random “collisions” of system particles with thermal bath particles. After each collision, the velocity of the randomly chosen system particle is reset to a new value that is randomly drawn from the Maxwell-Boltzmann distribution corresponding to the desired temperature. In practice, the frequency of random collisions is usually chosen such that the decay rate of energy fluctuations in the simulation is comparable to that in a system of the same size embedded in an infinite thermal bath. This method is simple and consistent with a canonical ensemble, but it introduces drastic change to the system dynamics. It is therefore not appropriate to use the Andersen method to study dynamical properties although it is appropriate to study static properties such as density or pressure.[2]

A more practical approach is the Berendsen method.[245] Just as in the Anderson method, the system is coupled to an imaginary external thermal bath held at a fixed temperature $T$. However, the exchange of thermal energy between the system and the thermal bath is much gentler. Instead of drastically resetting the velocity of the particle to a new value, the velocity of the particle is gradually scaled by multiplying it by a factor $\lambda$ given by

$$\lambda = \left[1 + \frac{\Delta t}{\tau_T} \left( \frac{T}{T_{ins}} - 1 \right) \right]^{1/2}$$

(3-9)

where $\Delta t$ is the time step, and $\tau_T$ is the time constant of the coupling. In this way, the velocities of the particles are adjusted such that the instantaneous kinetic temperature $T_{ins}$ approaches the desired temperature $T$.

The strength of the coupling between the system and the thermal bath can be controlled by using an appropriate coupling time constant. If a quick temperature control
is desired, a small coupling time constant can be chosen. Consequently, the value of $\lambda$
will be big and the change of the velocity will be drastic. On the other hand, if a weak
coupling is needed to minimize the disturbance of the system, a large value can be
assigned to the coupling time constant. In the evaluation of their own method,[245] Berendsen et al. concluded that static average properties were not significantly affected
by the coupling time constant, but the dynamic properties were strongly dependent on the
choice of the coupling time constant. Their testing showed that reliable dynamic
properties could be derived if the coupling time constant was above 0.1 ps.

The Berendsen method is very flexible in that the coupling time constant can easily
be varied to suit the needs of a given application. The biggest advantage of the Berendsen
method over the Anderson method is that it gently modifies the velocities, and therefore,
the change of the system dynamics is not so dramatic. However, caution must be taken
when using the Berendsen method because it does not rigorously reproduce the canonical
ensemble, and thus the distribution generated from this method is wrong although the
averages are usually correct.

The Berendsen method implemented in our simulations is the one used by our
collaborators at the University of Louisville. Based on their simulation experience, the
ratio of $\frac{\Delta t}{\tau_\gamma}$ in Equation (3-9) is set to be 0.1 because it gives the best compromise
between ideal temperature control and disturbance of the physical behavior of the system.

3.1.3 Variation of GLEQ Approach and a Combined Thermostat of GLEQ
Approach and Berendsen Method

In their MD simulations of energetic particle beam deposition, Haberland et al.
claimed that the regular GLEQ approach was not good enough to reduce the artificial
effects caused by the reflected waves from the boundary of the simulation box.[256] Their
system contained heavy clusters of more than 500 metal atoms per cluster, and the incident energy was typically in the keV range. They suggested an improved method in which the original thermostat atoms were replaced by fewer, heavier atoms. This allows one to choose a large thermostat zone without losing computational efficiency. Therefore, the backscattering of the elastic wave could be sufficiently delayed. In addition, the atoms at the boundary of the impact zone and the replacing thermostat zone are damped relative to the motion of their neighbors. This is an efficient damping mechanism, especially for the high frequency part of the reflected wave. However, the replacing thermostat lattice should have the same elastic properties as the bulk and match the lattice structure of the impact zone. This is relatively easy to achieve for FCC materials but nontrivial for materials with other lattice structures.

Although Haberland’s modified GLEQ approach is presently restricted to FCC materials, it works well at damping the motion and energy of the atoms at the boundary between the impact zone and the thermostat zone. This improvement can be readily included in the conventional GLEQ approach. In this study, a modified GLEQ approach, called the MGLEQ method, that includes extra damping for those boundary atoms and is applicable to systems of any crystal structure, is discussed. It is also rigorously tested to assess its effectiveness to both control the system temperature and reduce the amplitude of reflected energy waves.

Comparing the GLEQ approach with the Berendsen method, the GLEQ approach makes more physical sense and modifies atomic velocities more gently. Nevertheless, the GLEQ approach involves extra calculations of forces; therefore it is slightly more complicated and time-consuming than the Berendsen method. In this work, a combined
thermostat scheme of the GLEQ approach and the Berendsen method (hereafter denoted as BnG) is applied to the thermostat atoms as well. The combination is realized by dividing the original thermostat zone into two smaller zones: the one that directly borders the impact zone has the GLEQ scheme applied to it while the other has the Berensen scheme applied to it. Testing is done to assess whether this combined method combines the advantages of these two methods.

### 3.2 Testing Systems

The deposition of a single C$_{20}$ molecule on a hydrogen-terminated diamond (111) substrate at room temperature (300 K) is considered as a test of these four thermostat schemes. The initial distance between the depositing carbon cluster and the substrate is around 4 Å and the C$_{20}$ is deposited along the surface normal. The substrate contains an impact zone of atoms that is 2.4 nm × 2.4 nm × 1.0 nm. This impact zone is embedded in a thermostat zone of atoms with four walls that are 1.0 nm thick and a bottom layer that is 1.6 nm deep, as schematically illustrated in Figure 3-1. The dimensions of the whole substrate are therefore 3.4 nm × 3.4 nm × 2.6 nm. The number of atoms contained in the impact zone and the thermostat zone is 1,280 and 4,320, respectively. The bottom hydrogen layer is fixed to keep the substrate from reconstructing or moving.

Various incident energies (1 eV/atom, 5 eV/atom, 10 eV/atom, 20 eV/atom and 40 eV/atom) are considered. The REBO potential$^{[211]}$ coupled with long-range Lennard-Jones (LJ) potentials$^{[2]}$ is used to calculate the interatomic forces for the atoms in the cluster and in the impact zone. These atoms are denoted as active atoms. The velocities of the atoms in the thermostat zone are modified using the four temperature control schemes described in Section 3.1 to adjust the energy flow within the system. These atoms are therefore called thermostat atoms.
3.3 Results and Discussion

Deposition at 1 eV/atom is considered first. This incident energy is well below the binding energy of the carbon atoms in the $C_{20}$, which is approximately 5.9 eV/atom.$[^{66}]$ Therefore, during deposition, the original fullerene cage structure is not destroyed although deformation is observed. The degree of deformation induced by the collision varies slightly when different temperature control methods are applied to the thermostat atoms. The cluster only deforms a little in both the GLEQ and MGLEQ approaches, but it deforms more in the Berendsen and BnG methods. In all cases, the cluster does not attach to the substrate; instead, the deformed cluster bounces back into the vacuum and gradually recovers its original cage structure.

A reference simulation, in which the REBO potential coupled with the LJ potential is used to consider the interatomic forces in both the impact and thermostat zones, is performed at the incident energy of 1 eV/atom. In this case, all the atoms (except the bottom fixed hydrogen atoms) follow normal Newtonian dynamics. Since there is no special temperature control method introduced, a big substrate is required to dissipate the extra energy. In this reference simulation, the same impact zone is thus embedded in a
much bigger thermostat zone (which contains 14,374 thermostat atoms). The dimensions of this reference substrate are 5.2 nm × 5.2 nm × 3.1 nm. In this reference simulation, although there is no damage to the fullerene molecule upon collision, its original cage structure deforms significantly. The whole deformed molecule then leaves the substrate and slowly recovers. The temporal evolutions of the substrate temperature in the reference simulation and the simulations using the four temperature control methods are plotted in Figure 3-2. Even if the thermostat zone in the reference substrate is at least

Figure 3-2. The temporal evolution of the substrate temperature in the reference simulation and the simulations using the four temperature control methods at the incident energy of 1 eV/atom.

three times as big as the thermostat zone used in the simulations where special temperature control methods are applied, the energy dissipation obviously is not effective in this reference substrate because the temperature fluctuates about 392 K. In contrast, after 3 ps, the substrate temperature is less than 320 K when various temperature control methods are employed (314 K in the case of the GLEQ and MGLEQ approaches, 317 K and 318 K when the Berendsen method and the combined thermostat of GLEQ approach and Berendsen method are used, respectively). This finding provides direct evidence as to
why effective temperature control methods are necessary in the simulation of energetic deposition at constant temperature. The four temperature control methods perform equally well at this low incident energy in that the four curves essentially overlap, as displayed in Figure 3-2.

![Figure 3-2](image)

Figure 3-2. The temporal evolution of the substrate temperature in the simulations using the four temperature control methods at the incident energy of (a) 5 eV/atom, (b) 10 eV/atom.

When the same deposition occurs at 5 eV/atom, the behavior of the system is almost the same in all the four cases where the different temperature control methods are used. This incident energy is high enough to induce reactions between the cluster and the substrate. Therefore, although no apparent damage to the fullerene molecule is observed, the severely deformed cluster sticks to the substrate and tends to recover its cage structure during atomic relaxation after the collision. The outcomes of deposition at 10 eV/atom are similar to the outcomes predicted to occur at 5 eV/atom except that the cage structure of the C_{20} is destroyed at 10 eV/atom. The damaged cluster also attaches to the top of the substrate. The changes of the substrate temperature are portrayed in Figures 3-3(a) and
(b) for depositions at 5 eV/atom and 10 eV/atom, respectively. As shown in these figures, the change of the substrate temperature during the first 1 ps is different when different temperature control methods are used. It appears that the Berendsen method reduces the temperature most dramatically at the beginning. However, during the subsequent process, the four curves overlap.

When the deposition takes place at 20 eV/atom, the cage structure of the C<sub>20</sub> molecule is completely destroyed. The fragments from the cluster react with the substrate carbon atoms and form a strongly adhered film. The phenomena observed are more or less the same in the systems where different temperature control methods are used, but the difference in the substrate temperature change is more apparent. As shown in Figure 3-4(a), during the first 1 ps, the Berendsen method induces the most dramatic decrease while the reduction in the temperature is much gentler using the other three methods. At about 1.5 ps, the fluctuation in the temperature begins to stabilize at about 340 K in the system using the Berendsen method. However, the stabilization is not achieved in the systems where the other three methods are used until after 2 ps. The GLEQ approach appears to be the best method to control the temperature at this incident energy because the substrate temperature after 3 ps is 327 K in the GLEQ approach but is about 335 K using both the MGLEQ approach and the BnG method.

A direct way to demonstrate the energy dissipation capability of the temperature control scheme is to monitor the change of the system energy. In the deposition system considered here, the largest change in the system energy comes from the kinetic energy change because only those atoms involved in chemical reactions will have a substantial change in their potential energy, and the fraction of these atoms in the considered
Figure 3-4. The temporal evolution of (a) the substrate temperature and (b) the kinetic energy per active atom in the simulations using the four temperature control methods at the incident energy of 20 eV/atom.
deposition system is very small. Therefore, the change of the kinetic energy can represent the change of the whole system energy. Figure 3-4(b) gives the temporal variations of the kinetic energy per active atom for deposition at an incident energy of 20 eV/atom. This figure better separates the four curves corresponding to each temperature control method than the temporal evolution of the substrate temperature. As clearly shown in Figure 3-4(b), before the relaxation starts (at about 1 ps), the Berendsen method dissipates the extra energy most quickly, and the combined thermostat of the GLEQ approach and the Berendsen method dissipates the energy most slowly. The curves generated from the GLEQ and MGLEQ approaches overlap at this early stage. However, at the relaxation stage, the curve of the GLEQ approach begins to separate from the curve of the MGLEQ approach. Apparently, the MGLEQ approach does not reduce the energy as much as the GLEQ approach under this deposition condition. While the average kinetic energy fluctuates about 0.06 eV/atom in the Berendsen method after 1.5 ps, this quantity continues to drop in both the GLEQ approach and BnG method. At 3 ps when the simulation stops, the GLEQ approach and the combined thermostat appear to have performed the best at removing the excess energy in the system.

Although the GLEQ approach is the best among the four methods for energy dissipation and temperature control at 20 eV/atom, it becomes the worst at a higher incident energy of 40 eV/atom. As demonstrated in Figure 3-5, both the final substrate temperature and the average kinetic energy per active atom are the highest in the system where the GLEQ approach is used. The performance of the Berendsen method is not satisfactory either. The best method in this case is the combined thermostat of the GLEQ approach and the Berendsen method, which results in the lowest substrate temperature
Figure 3-5. The temporal evolution of (a) the substrate temperature and (b) the kinetic energy per active atom in the simulations using the four temperature control methods at the incident energy of 40 eV/atom.
and the average kinetic energy. The modified GLEQ approach also performs better than either the GLEQ approach or the Berendsen method.

Snapshots from the simulations at various moments during the deposition at the incident energy of 40 eV/atom demonstrate the different responses of the substrate when different temperature control schemes are used (Figure 3-6). At 3 ps when the simulation stops, the substrate where the GLEQ approach is employed suffers the smallest amount of damage; however, the largest amount of disorder to the substrate structure is observed in the surface where the combined thermostat is used. Between approximately 0.08 ps to 0.24 ps, the compressed substrate moves upward. Such movements are depicted in Figure 3-7 for the four substrates with different temperature control schemes applied. Although the four displacement fields look similar, the details are different, especially the displacements of the atoms in the top right corner (see the circled areas in Figure 3-7). The movement of these atoms shows a pattern of the reflected wave from the edge in the substrate using the GLEQ approach. This reflected wave could cause over-relaxation of the substrate atoms, which somewhat “heals” part of the damage to the structure. Such patterns are also seen in the substrates using the Berendsen method and the MGLEQ approach, but are not clearly present in the substrate where the combined thermostat is used. Therefore the combined thermostat of the GLEQ approach and the Berendsen method more satisfactorily suppresses the amplitude of the reflected wave than the other three schemes.

In summary, at low incident energies (≤ 10 eV/atom in this study), the four temperature control methods are all sufficient to control the system temperature and delay the backscattering of the reflected wave. When the incident energy becomes high, the
Figure 3-6. Snapshots of the systems using the four temperature control methods at various moments at the incident energy of 40 eV/atom.

Figure 3-7. The displacement fields from $t = 0.08$ ps to $t = 0.24$ ps in the cross section of the (111) plane using the four temperature control methods at the incident energy of 40 eV/atom. (a) GLEQ approach, (b) Berendsen method, (c) modified GLEQ approach, and (d) the combined thermostat of the GLEQ approach and the Berendsen method.
different performance of the four methods becomes apparent. This difference results from their different abilities to absorb energetic waves propagating through the system at various frequencies. The Berendsen method reduces the energy quickly at the early stage of the process, and quickly brings the system to equilibrium. But the Berendsen method is not as efficient at absorbing enough of the reflected wave when the incident energy is high, which results in a relatively high temperature and energy when the system reaches the equilibrium state. At moderate incident energies (for example, 20 eV/atom), the GLEQ approach is still capable of dissipating the extra energy. Nevertheless, it fails at higher incident energy. This result is consistent with Haberland’s conclusion as mentioned in Section 3.1.3.\cite{256}

The modified GLEQ approach that introduces extra damping at the boundary atoms between the impact zone and the thermostat zone does indeed improve the capability of the system to control the temperature as well as absorb the reflected wave when the incident energy is high. The combined thermostat of the GLEQ approach and the Berendsen method removes the excess energy in the most gradual manner, and the system is usually the slowest one to reach the equilibrium. But, this simple combination is superior to either the GLEQ approach or the Berendsen method, especially at a high incident energy if enough time is allowed for the relaxation. This can be explained as follows. The velocity adjustment algorithm in the GLEQ approach is different from that in the Berendsen method. The frequency range of the energetic wave that could be effectively absorbed by the GLEQ approach is therefore different from the Berendsen method. When the cluster collides with the substrate at a high incident energy, the range of the resultant energy wave frequency is wider, which may cover both the effective
ranges of the GLEQ approach and the Berendsen method. Therefore, when neither the GLEQ approach nor the Berendsen method is able to completely absorb the reflected wave, their combination can do much better.

However, if the substrate size is too small relative to the incident energy, none of the temperature control schemes will work well enough to remove the extra energy. In this study, a small substrate with dimensions of 2.8 nm × 2.8 nm × 1.3 nm is also considered in the deposition at 40 eV/atom. The number of active atoms and thermostat atoms contained in this substrate are about $\frac{1}{3}$ of those in the substrate considered above.

Both the temporal evolution of the substrate temperature (Figure 3-8(a)) and the average kinetic energy per active atom (Figure 3-8(b)) are essentially the same in the systems where the four temperature control schemes are used. As given in Figure 3-8(a), the substrate temperature finally fluctuates at about 520 K, which is too much higher than the desired temperature. After 1.5 ps, the system appears to reach equilibrium and

![Figure 3-8](image-url)

Figure 3-8. The temporal evolution of (a) the substrate temperature and (b) the kinetic energy per active atom in the depositions on the small substrate using the four temperature control methods at the incident energy of 40 eV/atom.
extended relaxation does not help to reduce the temperature and the energy, which indicates the reflected wave bouncing back and forth within the system.

### 3.4 Conclusions

In deposition experiments, the temperature of the substrate experiences a thermal spike when the incident particles collide with the substrate particles. The heat is then conducted away from the site of the collision quite quickly through the substrate, causing the temperature to drop exponentially.\(^{[254]}\) Appropriate temperature control methods, which can effectively dissipate extra energy in a system, are thus necessary to model such processes. The dissipation of extra energy not only helps to control the temperature but also absorbs the artificial reflected wave. In this chapter, four temperature control methods are used to model energetic cluster deposition on a solid substrate, which is a stringent test of temperature control methods. These methods include the GLEQ approach, the Berendsen method, a variation of the GLEQ approach where extra damping is introduced to the boundary atoms between the impact zone and the thermostat zone, and a combined thermostat of the GLEQ approach and the Berendsen method.

The performance of the temperature control methods depends on the incident energy and the substrate size. No matter which method is chosen, a large enough substrate is first required to realistically model the deposition process. The Berendsen method is very effective at removing excess energy at the early stage; however, the resultant equilibrium properties are not always the best. The GLEQ approach using the Debye solid model performs well if the incident energy is not too high. At a high incident energy, the modified GLEQ approach is better than the regular GLEQ algorithm due to the extra damping. Surprisingly but not unexpectedly, the simple combination of the GLEQ approach and the Berendsen method appears to be successful at controlling the
system temperature when either the GLEQ approach or the Berendsen method fails at a high incident energy.

It should be recognized that there is no realistic counterpart to the thermostat atoms because they do not obey Newton’s second law. The number of thermostat atoms should be large enough to bring the system temperature to the desired value. But in order to get reliable simulation predictions, the thermostat zone should be far away from the area where the processes of interest occur. This requires the impact zone, where the atoms follow the normal Newtonian dynamics, to be large enough to be realistic while remaining within the limitations of the available computer system. The following simulations model the deposition of particles at moderate incident energies. Each incident particle contains less than 50 atoms whose atomic number is less than 10. In these simulations, the substrate with appropriate size and arrangement of the impact zone and the thermostat zone is first determined depending on the incident energy and the size of the incident particle. The GLEQ approach is chosen because this approach is good enough to handle the deposition of small particles at moderate incident energies and it realistically describes the exponential decrease of the substrate temperature.\cite{254}
CHAPTER 4
THIN FILM FORMATION VIA ORGANIC CLUSTER BEAM DEPOSITION

Cluster deposition on solid substrates has received growing attention over the last three decades. Compared to single atom deposition, cluster deposition is unique in that it produces a high concentration of energy and mass in a very localized region. The interaction between the cluster and the substrate occurs just near the surface. And the cluster won’t penetrate deeply into the bulk. As a result, there is relatively little damage to the substrate. This method is therefore well suited to generate thin films.[19, 24, 25] The properties of the thin film can be controlled by changing the deposition conditions, such as the incident energy, impact species, cluster size, deposition angle, substrate temperature, etc. In this study, thin film formation through organic molecular cluster beam deposition is examined by using molecular dynamics simulations. The second generation reactive empirical bond order (REBO) potential parameterized by Brenner et al. for hydrocarbon systems[211] coupled with the long-range Lennard-Jones (LJ) potential is used to calculate the interatomic interactions. Incident clusters with different types of intracluster bonding are considered. The effects of the incident angle and the deposition direction are examined.

4.1 Simulation Details

The surface investigated in this study is hydrogen-terminated diamond (111) substrate made up of 26 atomic layers that contains 13700 – 13900 atoms with a planar impact area of 69 Å × 40 Å. This configuration is chosen because it was found previously that the 26-layer surface is best at removing the artificial rebounding of the deposition
energy and preventing it from interfering with the reactions occurring at the surface at the highest incident energy considered.\cite{102} Two-dimensional periodic boundary conditions are applied within the impact plane to mimic a semi-infinite system. The bottom hydrogen layer is fixed. The next six carbon layers and 5 to 6 rows of atoms on the slab edges have Langevin frictio nal forces and random forces applied. That is, the GLEQ approach is used to dissipate the extra heat accumulated on the surface upon deposition, and at the same time, to prevent the reflection of the impact energy from the edges of the slab. The remaining surface atoms and all the cluster beam atoms are active atoms, which are free to move in response to the applied forces without any constraints. Figure 4-1 shows the arrangement of the thermostat atoms and the active atoms in the substrate. Before the deposition, the surface is equilibrated at 500 K to achieve a relaxed structure with optimized atomic configurations, and then cooled to the simulation temperature of 300 K.

Figure 4-1. The arrangement of the thermostat atoms (gray) and the active atoms (black) within the substrate. The top and bottom spheres in the side view are hydrogen atoms.
Three cluster beams with different types of intracluster bonding are examined in this study. These are a van der Waals cluster beam of ethylene ($\text{C}_2\text{H}_4$) molecules, a beam of adamantane ($\text{C}_{10}\text{H}_{16}$) molecules, and a beam of fullerene molecules ($\text{C}_{20}$). In thin film formation through energetic cluster deposition, cluster size is a very important factor. In contrast to the metallic cluster deposition, our previous simulations of thin film formation via organic cluster deposition predicted that smaller clusters of a few tens of atoms produced thin films more efficiently than large clusters of several hundred atoms.\textsuperscript{[99]} This prediction is consistent with the experimental fact that in ICBD technique, which is a successful method to produce organic thin films,\textsuperscript{[25, 28-30]} only small clusters prevail.\textsuperscript{[26, 40, 41]}

Therefore, in this study, the van der Waals cluster beam of ethylene contains 8 ethylene molecules per cluster; the beams of adamantane and $\text{C}_{20}$ each contain one molecule per cluster. Although the number of atoms contained in each cluster in these three beams is quite different (48 for ethylene, 26 for adamantane, and 20 for $\text{C}_{20}$), all the individual clusters are roughly the same size and contain comparable amounts of carbon (16 C atoms for ethylene, 10 C atoms for adamantane, and 20 C atoms for $\text{C}_{20}$). Each of the three beams contains 20 clusters. All the beams are created through the repetition of a single cluster that has been equilibrated at 500 K and quenched to 5 K to minimize the internal kinetic energy of the cluster. Then 20 of the clusters are repeated in random translational and angular orientations so that they will not impact the surface with the same orientation or at the same point on the surface. Prior to deposition, each beam is placed about 4 Å above the surface; the distance between two consecutive clusters is also around 4 Å. This distance is chosen because it is long enough that the individual clusters
do not interact with one another in the beam and yet the deposition process is not too slow in these demanding computational studies.

This study is designed to compare the formation of thin films from cluster beams with different types of intracluster bonding, and to gain a better understanding of the effects of incident angle and impact direction. Therefore, depositions at angles of 0°, 15°, 45° and 60° from the surface normal for all the three incident species are considered. When the beam impacts the surface at an angle $\theta$, the total impact momentum ($\rho_{\text{total}}$), which is related to the total energy ($E_{\text{total}}$), can be divided into two none-zero components: the component normal to the surface ($\rho_{\text{normal}}$), which corresponds to $E_{\text{normal}}$ ($= E_{\text{total}} \cos^2 \theta$); and the component parallel to the surface ($\rho_{\text{lateral}}$), which corresponds to $E_{\text{lateral}}$ ($= E_{\text{total}} \sin^2 \theta$). When $\theta$ changes while $\rho_{\text{total}}$ and $E_{\text{total}}$ are fixed, both the normal and lateral components vary with angle. Consequently, two sets of deposition energies are considered — one where $E_{\text{total}}$ is constant at 400 eV/cluster while the ratio of $\rho_{\text{normal}}$ to $\rho_{\text{lateral}}$ decreases with increasing angle; and another where $\rho_{\text{total}}$ and $E_{\text{total}}$ change but $\rho_{\text{normal}}$ is constant (corresponding to a constant energy of 400 eV/cluster normal to the surface).

Deposition with $\rho_{\text{lateral}}$ along the [112] and [110] crystallographic orientations are investigated. The deposition system is schematically shown in Figure 4-2. For statistical purpose, five trajectories are carried out for each set of deposition conditions for each incident species. The averaged results are reported. All the simulations run for about 3 ps with 0.2 fs as the time step. The deposition occurs during the first 1 ps followed by the complete relaxation of the system during the next 2 ps.
4.2 Results

4.2.1 van der Waals Clusters of Ethylene

There is only the weak intermolecular van der Waals force keeping the ethylene molecules together within the cluster. During the deposition, the ethylene cluster flattens out and the molecules impact each other and dissociate into small segments. Many surface hydrogen atoms and some surface carbon atoms are removed, which facilitates the nucleation of the thin film, as shown in Figure 4-3(a). When the collision occurs at 0° and 15° with $E_{\text{total}}$ of 400 eV/cluster, the surface experiences a significant amount of elastic deformation upon impact and some plastic deformation up to 3-4 carbon layers (Figure 4-3(b)). Typically, the thickness of the resultant thin films is about 6-7 Å. As the impact angle increases, a larger fraction of the surface deformation is elastic and the plastic deformation is limited to the top one or two carbon layer(s). At 60°, many of the clusters and their fragments “slide” along the surface, and the resultant thin film is only about 3 Å thick. A typical snapshot is shown in Figure 4-3(c). The average maximum penetration depth of the beam fragments slightly increases as the deposition angle
Figure 4-3. Representative snapshots from the simulations of ethylene cluster beam deposition on the hydrogen terminated diamond (111) surface. The black atoms are incident carbon, the gray atoms are surface carbon, and the white atoms are hydrogen. (a) A representative snapshot of the configuration at time = 0.05 ps, the early stage of the deposition; (b) the relaxed configuration at time = 3 ps at 0º; (c) the relaxed configuration at time = 3 ps with $E_{\text{total}} = 400 \text{ eV/cluster at } 60^\circ$ along $[110]$; (d) the relaxed configuration at time = 3 ps with $E_{\text{normal}} = 400 \text{ eV/cluster at } 60^\circ$ along $[110]$. 

$E_{\text{total}}$ and $E_{\text{normal}}$ represent the total and normal energies of the cluster, respectively.
decreases. But at all the incident angles, the penetration depth is about 1 Å. Approximately 1% of the surface atoms are sputtered for all the angles considered.

When the deposition occurs with constant normal momentum equivalent to the normal incident energy of 400 eV/cluster, severe permanent disorder of the surface is predicted to occur, especially at large angle impacts (compare Figure 4-3(c) vs. Figure 4-3(d)). In addition, many more surface carbon atoms are pushed toward the surface region and become part of the film. The film thickness is about 7 Å at all angles. The average maximum penetration depth of the beam fragments increases as the angle increases (from about 0.7 Å at 15º to about 2.7 Å at 60º). The amount of surface sputtering also increases with the angle, from about 0.7% at 15º to about 4.0% at 60º.

Figure 4-4 summarizes the percentage of the carbon atoms from the incident ethylene clusters that adhere to the surface at various incident angles. When the depositions occur with $E_{\text{total}}$ of 400 eV/cluster, the amount of adhesion decreases monotonically as the incident angle increases, although the result at 15º is about the same as the normal impacts when the standard deviation is considered. This suggests the deposition with high impact momentum normal to the surface would facilitate thin film nucleation. When the cluster beam is directed to the substrate with a constant normal impact momentum (corresponding to $E_{\text{normal}} = 400$ eV/cluster), the adhesion percentage is about the same for the 0º, 15º and 45º depositions. However, at 60º, the amount of the nucleated thin film is still lower than those smaller angle depositions, although the decrease is not so dramatic as when $E_{\text{total}} = 400$ eV/cluster. In fact, if the deposition results at $E_{\text{normal}} = 400$ eV/cluster are compared with the results at $E_{\text{total}} = 400$ eV/cluster, one can see that the amount of adhesion increases significantly in the case of $E_{\text{normal}} =$
400 eV/cluster, especially when the deposition occurs at large angles such as 45° and 60°. This result again justifies the important role played by the normal impact momentum in the film nucleation and growth. Deposition along different crystallographic orientations yields the same trend. The adhesion percentage along different directions at the same angle is approximately the same. This indicates that the thin-film nucleation and growth has little dependence on the incident direction of the beam.

Figure 4-4. Percentage of carbon atoms in the ethylene clusters that adhere to the surface as a function of incident angle. (A) Deposition with $E_{\text{total}} = 400$ eV/cluster along $[112]$, (B) deposition with $E_{\text{normal}} = 400$ eV/cluster along $[112]$, (C) deposition with $E_{\text{total}} = 400$ eV/cluster along $[110]$; (D) deposition with $E_{\text{normal}} = 400$ eV/cluster along $[110]$.

The structure of the nucleated thin film is analyzed quantitatively by determining the coordination number and carbon connectivity of the carbon atoms in the film. The former shows the hybridization characteristics of the carbon atoms in the film, and the latter indicates the relative amount of linear structure versus branched, and/or networked structure in the film. All the films are found to be essentially amorphous. The incident
angle has little effect on the film structure. The hybridization of the carbon atoms ranges from sp to sp$^3$ with the majority sp$^2$-hybridized (40-50%). The simulations predict more sp-hybridized carbon atoms and less sp$^3$-hybridized carbon atoms in the film when the total incident energy is higher, in agreement with the previous studies.$^{95, 97, 98}$ Most of the carbon atoms are connected to one another in linear chains, while about 20% are branched carbons and even fewer (less than 2%) are networked. Deposition along different crystallographic orientations does not significantly affect the overall structure of the film.

4.2.2 Admantane Molecules

Adamantane is a cage hydrocarbon composed of four cyclohexane chairs, as shown in Figure 4-5. This molecule is quite stable because it possesses no angle strain (all the carbon atoms are perfectly tetrahedral and sp$^3$ hybridized) and no torsional strain (all the carbon-carbon bonds are perfectly staggered).$^{259}$ Despite the similarity of the bonding in adamantane to the bonding in diamond, the deposition of a beam of adamantane molecules in a previous study was not predicted to produce diamond-like thin films; instead, the film contained primarily sp$^2$-hybridized carbon.$^{102}$

![Figure 4-5. Molecular structure of adamantane.](image)

When the beam of adamantane molecules impacts the surface with a total incident energy of 400 eV/cluster, the adamantane molecules dissociate on contact with the surface and the original cage structure is broken into chain-like fragments. In addition, the surface deforms and some of the hydrogen atoms from the topmost layer are
displaced, leaving nucleation sites for the fragments to attach to the surface, as shown in Figure 4-6(a). As the incident angle increases, the surface experiences less deformation, and longer chains survive. Nevertheless, no cage structures remain after deposition at any of the angles considered. Representative snapshots of the resultant thin film are shown in Figure 4-6(b) and (c). The resultant thin films are typically about 4-7 Å thick. Atoms from the cluster beam can travel approximately 1 Å into the surface, with the deposition processes at 0º and 15º resulting in slightly deeper penetrations than the deposition processes at 45º and 60º. About 1% of the original surface atoms are knocked out of the surface. This sputtering effect is slightly greater at large incident angles because of the high lateral impact momentum associated with the large angle deposition.

As is the case for the ethylene cluster beam, when the adamantane is deposited with a constant normal momentum that corresponds to the normal incident energy of 400 eV/cluster, the surface is damaged more severely as the incident angle increases (Figure 4-6(d)), and large numbers of surface atoms are sputtered out of the surface. The cage structure of the adamantane molecules is destroyed during deposition, either from the initial impact with the surface or from gas-phase collisions with the sputtered fragments leaving the surface. The latter is not seen for depositions with total incident energy of 400 eV/cluster. The molecules consequently break into short chains that contain 2-3 carbon atoms and various numbers of hydrogen. Some of these chains stick to the surface and some scatter away. However, as the deposition process continues, these short chains can react with one another to form longer chains. The resultant thin film is about 7-11 Å, which is significantly thicker than the film formed when the total incident energy is 400 eV/cluster.
Figure 4-6. Representative snapshots from the simulations of adamantane molecular beam deposition on the hydrogen terminated diamond (111) surface. The same color scheme as in Figure 4-2 applies. (a) A representative snapshot of the configuration at time = 0.05 ps; (b) the relaxed configuration at time = 3 ps at 0º; (c) the relaxed configuration at time = 3 ps with $E_{total} = 400$ eV/cluster at 60º along [110]; (d) the relaxed configuration at time = 3 ps with $E_{normal} = 400$ eV/cluster at 60º along [110].
Figure 4-7. Percentage of adamantane carbon atoms that adhere to the surface as a function of incident angle. (A) deposition with $E_{\text{total}} = 400 \text{ eV/cluster}$ along [112], (B) deposition with $E_{\text{normal}} = 400 \text{ eV/cluster}$ along [112], (C) deposition with $E_{\text{total}} = 400 \text{ eV/cluster}$ along [110]; (D) deposition with $E_{\text{normal}} = 400 \text{ eV/cluster}$ along [110].

The percentage of carbon atoms from the adamantane molecules that remain chemisorbed to the surface at various incident angles is shown in Figure 4-7. As what happens in the deposition of ethylene clusters, the amount of adhesion decreases as the incident angle increases, while $15^\circ$ impacts are as efficient to produce thin films as the normal impacts. However, as indicated in Figure 4-7, the amount of adhesion at $45^\circ$ when the deposition occurs with $E_{\text{total}} = 400 \text{ eV/cluster}$ is comparable to what happens when the deposition occurs with $E_{\text{normal}} = 400 \text{ eV/cluster}$. This is in contrast to the significant increase in the amount of adhesion predicted for the ethylene cluster beam deposition at $45^\circ$ when the beam is deposited with $E_{\text{normal}} = 400 \text{ eV/cluster}$ (see Figure 4-4). Finally, the deposition of adamantane molecules along different crystallographic orientations does
not result in noticeable differences in the adhesion percentage, in agreement with the
results predicted from the ethylene cluster deposition.

As seen in our previous study,[102] the bonding in the film resulted from the
adamantane deposition is predominantly sp$^2$-hybridized (40%-60%) and no more than
15% of the carbon atoms remain sp$^3$ hybridized. About 70%-80% of the carbon atoms are
connected to one another in a linear fashion, 30%-20% are branched, and less than 3%
are networked. Again, the film structure shows little dependence on either the incident
angle or the crystallographic orientation.

4.2.3 C$_{20}$ Molecules

C$_{20}$ with a cage structure is the smallest member in the fullerene family. It has no
hexagons but 12 pentagonal faces. Its surface thus has high curvature, which severely
bends and strains the bonds between the carbon atoms. Besides the fullerene structure,
both experimental and theoretical work has shown that several other structures for C$_{20}$
exist, such as linear structure (chain), monocyclic and/or bicyclic rings, graphitic sheet,
and corrannulene structure (bowl).[260-265] However, different theoretical calculations give
contradictory results as to the energetic stability of these isomers. Quantum Monte Carlo
calculations suggest that bowl and ring isomers are more energetically stable than
fullerene structure.[260, 261] Quantum molecular dynamics simulations,[262] coupled cluster
calculations,[263] and density functional calculations with local spin density and gradient-
corrected approximations[264] predict the fullerene structure is the minimum energy
configuration. However, experimental measurements show that the fullerene structure of
C$_{20}$ is not favored under the conditions of experiments. The major reason lies in the
complicated experimental conditions, for example, high temperatures and charge
states.[264, 265] The bonding in C$_{20}$ fullerene is unique in that it is sp$^2$ hybridized with $\pi$-
bonding that is so distorted that it is nearly sp\(^3\) hybridized. Several groups have studied the deposition of fullerene on surfaces\(^{36, 63, 65, 66, 70, 75, 91-94, 112, 266}\) and find that it can be used as a precursor of thin film growth.

In our simulations, the C\(_{20}\) cage flattens and breaks into fragments such as rings and chains when it hits the surface (see Figure 4-8(a)). As is the case in the depositions of both ethylene molecular beam and adamantane beam, during the deposition of C\(_{20}\) beam, the surface also deforms with the degree of deformation depending on the cluster energy and incident angle. For example, when the deposition occurs with the total incident energy of 400 eV/cluster, at 0° and 15°, elastic deformation can reach the 13\(^{th}\) surface carbon layer, while plastic deformation remains up to the 5\(^{th}\) surface carbon layers, as shown in Figure 4-8(b). When the incident angle is 45° or 60°, elastic deformation reaches only the 8\(^{th}\) carbon layer while plastic deformation only reaches the 3\(^{rd}\) carbon layer, as shown in Figure 4-8(c). However, when the deposition occurs at high incident energy, which, in this study, corresponds to the case where the beam is deposited to the surface at a constant normal momentum equivalent to a normal incident energy of 400 eV/cluster, significant permanent surface deformation appears at large incident angles (compare Figure 4-8(c) with Figure 4-8(d)).

During the depositions with the total incident energy of 400 eV/cluster, chain-like fragments that contain 5-6 carbon atoms form, and few surface carbon atoms are knocked loose. The resultant thin film is about 6-10 Å thick. In addition, the film fragments often have more than one tethering points to the surface, giving the film strong adhesion to the diamond. Atoms from the C\(_{20}\) penetrate about 1 Å into the surface and around 1% of the
Figure 4-8. Representative snapshots from the simulations of C$_{20}$ molecular beam deposition on the hydrogen terminated diamond (111) surface. The same color scheme as in Figure 4-2 applies. (a) A representative snapshot of the configuration at time = 0.05 ps; (b) the relaxed configuration at time = 3 ps at 0º; (c) the relaxed configuration at time = 3 ps with $E_{\text{total}} = 400$ eV/cluster at 60º along [101]; (d) the relaxed configuration at time = 3 ps with $E_{\text{normal}} = 400$ eV/cluster at 60º along [110].
surface atoms are sputtered, with the deposition at large angles producing slightly more sputtering than deposition at small angles (0.9% at 60° and 0.5% at 0°).

When the C_{20} beam is deposited at a constant normal impact momentum that corresponds to the normal incident energy of 400 eV/cluster, the fullerene cages are broken into smaller fragments and fewer ring structures survive. The average penetration depth of atoms from the clusters is also deeper (1 Å at 15°, 1.3 Å at 45° and 2.3 Å at 60°). Large numbers of surface carbon atoms are sputtered from the surface. Surface sputtering increases significantly as the angle increases, from 0.6% at 15° to 4.8% at 60°. The resultant thin film is 8-10 Å thick, and contains more surface carbon atoms than when the total incident energy is 400 eV/cluster.

Figure 4-9. Percentage of carbon atoms in C_{20} clusters that adhere to the surface as a function of incident angle. (A) deposition with \( E_{\text{total}} = 400 \text{ eV/cluster} \) along [112], (B) deposition with \( E_{\text{normal}} = 400 \text{ eV/cluster} \) along [112], (C) deposition with \( E_{\text{total}} = 400 \text{ eV/cluster} \) along [110]; (D) deposition with \( E_{\text{normal}} = 400 \text{ eV/cluster} \) along [110].
The amount of carbon atoms from the $C_{20}$ molecular beam adhered to the surface resulting in the thin film formation decreases as the incident angle increases, as shown in Figure 4-9. The results show no significant dependence on crystallographic orientation, and the 15° depositions always generate similar results to the normal angle depositions. Additionally, the amount of adhesion is relatively insensitive to cluster energy at all the incident angles considered.

The coordination number and carbon connectivity of the film carbon atoms are also examined. The results show that the film contains 40%-50% $sp^2$ hybridized carbon and 30%-50% $sp$ hybridized carbon. Less than 10% are $sp^3$-hybridized. The carbon atoms are mainly connected in a linear manner (50%-70%), a significant number (50%-30%) are branched, and no more than 4% are networked. These results as well as those for the depositions of ethylene clusters and adamantane molecules are summarized in Tables 4-1 and 4-2.

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</tr>
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### 4.3 Discussion

During the deposition, about 60%-80% of the clusters’ kinetic energy is transformed into surface kinetic energy, and more than 90% of the excess surface kinetic energy is dissipated through the Langevin thermostat atoms in the surface.\[95, 97, 98, 100]\] The
effectiveness of the application of the Langevin thermostat is crucial for the realistic dissipation of the excess surface kinetic energy and is therefore closely examined in this study. The averaged temperature of the surface Langevin atoms and the non-thermostat atoms is measured separately after the relaxation. Among the three incident species, C\textsubscript{20} deposition results in the highest surface temperature because it has the most localized energy accumulation, which makes the transfer of incident energy to the surrounding substrate atoms the least efficient. But as expected, for all the three species, the average temperature of the surface Langevin atoms is about 300 K (the simulation temperature), while the temperature of the non-thermostat atoms is slightly higher than 300 K. Therefore, the current system set-up is effective enough to maintain the system temperature as required for all the three incident cluster beams.

Although the three cluster beams used in this study are quite different from one another, their deposition results share some significant similarities. In all cases, the deposition process destroys the original structure of the cluster, regardless of the type of bonding holding the cluster together. Both adamantane and C\textsubscript{20} disintegrate into chains or rings. This finding for C\textsubscript{20} differs from the results of some other studies,\textsuperscript{[91, 94]} which predict that its cage structure can either survive after surface impact or recover during the following relaxation. This is because the incident energy used here is at least two times higher than the molecular binding energy of the C\textsubscript{20} (which is about 118 eV/molecule) while the energy considered in those studies is much lower.

Despite the rigid nature of the diamond, the substrate experiences various degrees of damage depending on the incident energy and the incident angle. The depth of the damage to the surface varies from 2 Å to 8 Å, which indicates that the deposition process
modifies only a shallow region of the surface. When the deposition takes place at a total incident energy of 400 eV/cluster, the damage to the surface decreases with increasing incident angle because of the large component of momentum normal to the surface at small angles. However, when the normal impact momentum is kept constant, which corresponds to an energy of 400 eV/cluster normal to the surface, the damage to the surface is more severe at large angles, especially in the lateral direction, because of the large lateral component of the impact momentum that breaks a large number of surface bonds.

Surface sputtering is predicted to occur in all the simulations and the lateral momentum component is a major factor in controlling the sputtering effect. For instance, in the depositions at a constant total impact momentum, which is equivalent to a total incident energy of 400 eV/cluster, more surface atoms are sputtered at large incident angles where the lateral impact momentum is large. In cases where the impact momentum normal to the surface are held constant, the sputtering of surface atoms at large angles (45° and 60°) is about 2-4 times the sputtering of surface atoms at small angles (0° and 15°) because the lateral component of the impact momentum increases significantly with increasing angle.

Deposition of single-atomic ion beam can only result in smooth thin film at oblique angles. While in cluster beam deposition, Yamamda et al. reported the substrate roughness increased monotonically with increasing incident angle. However, the depositions of all the three cluster beams in this study show little dependence of the smoothing effect on the incident angle. In fact, the resultant thin film thickness is about 3-7 Å from the deposition of ethylene molecular clusters, 4-7 Å from adamantane
clusters, and 6-10 Å from C_{20} clusters, when the deposition occurs with a total incident energy of 400 eV/cluster no matter at what angle. It is noted though the incident particles used in this study are clusters containing more than one atom but less than 50 atoms, the size of which is significantly smaller than what is used in Yamada’s study (3000 Ar atoms/cluster). Therefore, it is suggested the dependence of resultant film roughness on the incident angle is essentially controlled by the size of the energetic particles.

In the incident energy range used here, the average penetration depth of atoms from the clusters is no more than 3 Å. The penetration depth is determined by the initial atomic velocity normal to the surface, \( v_{\text{normal}} \), and the ability of the burrowing atom to overcome the resistance force exerted by the surface atoms. When the clusters impact the surface with a constant total momentum, the penetration depth is a little deeper at small angles than at large angles because of the higher \( v_{\text{normal}} \) in the former case. When the clusters impact the surface with constant momentum normal to the surface, although \( v_{\text{normal}} \) is the same, the lateral momentum of the incident atoms is much larger at large angles. Therefore, the species impacting at large angles have more ability to push surface atoms aside, which facilitates deeper penetration. As a result, the penetration depth of the same incident species increases with increasing incident angle when the deposition occurs at constant normal momentum.

The number of atoms from the molecules that remain chemisorbed to the surface is an indication of the efficiency in the generation of thin film via energetic particle deposition. These simulations predict that the amount of adhesion is not only related to the cluster energy (especially the incident energy normal to the surface), but also related to the incident angle. At the same incident angle, the greater the incident energy normal
to the surface, the greater the amount of thin-film adhesion. All the three beams considered in this study show a general trend of decreasing adhesion with increasing deposition angles. Nevertheless, the thin film generation results for small angles ($\theta \leq 15^\circ$) are nearly the same as the thin film generation results of normal-angle deposition.

Despite the differences in the original structures of the three clusters, the films that result from their deposition are similar to one another. They consist primarily of $sp^2$-hybridized carbon, and most of the carbon atoms in the film are connected to each other in a linear fashion (see Table 4-1 and Table 4-2). This is in agreement with the experimental studies that find the film properties are not affected by the specific structure of the incident species.[75] This can be attributed to the high incident energy used here and in those experimental studies. When the clusters are deposited on solid surface at high enough energy, the strong collision between the cluster and the surface can lead to a complete destruction of the original cluster structure and only the highly energetic atoms and radicals survive. Therefore, it is the properties of these energetic atoms and radicals, not the properties of the original clusters, that will determine the structure of the resultant thin film.

There are also important differences in the results of the depositions of ethylene cluster, adamantane, and $C_{20}$ beams. These differences arise from the different compositions and intracluster interactions of these three incident species, as well as the different interactions between the incident cluster and the surface. For example, both the deposition of the ethylene cluster beam and adamantane beam generate film containing large amounts (60%-70%) of hydrogen, while the film that results from the deposition of the $C_{20}$ beam is more like an amorphous carbon film, and only 40%-50% is hydrogen
(that has been incorporated into the film from the surface). This is because C\textsubscript{20} is a hydrogen-free molecule, whereas the ethylene and adamantane contain significant amounts of hydrogen. In addition, although most carbon atoms are sp\textsuperscript{2} hybridized in all the films generated from these three beams, the amount of sp\textsuperscript{3}-hybridized carbon is the highest (10\%-30\%) in the film formed from ethylene cluster beam deposition and the lowest (<10\%) in the film from C\textsubscript{20} beam deposition. The carbon connectivity within the films is also slightly different. Specifically, the number of branched carbon atoms is the highest (30\%-50\%) in films produced from C\textsubscript{20} and the lowest (10\%-20\%) in films produced from ethylene.

There are also noticeable differences in the chemical reactions that the various species undergo. In the case of ethylene molecular clusters, the clusters are easily dissociated because the weak van der Waals bonds are easily broken. It is therefore possible to redistribute the incident kinetic energy to individual molecules through intermolecular collisions. Complex chemical reactions can take place among the molecules within the cluster as well as between the incident particle and the surface (and/or the sputtering fragments). However, in the case of the adamantane and C\textsubscript{20} beams, no reactions occur among the incident molecules because only one molecule exists in each cluster and direct intermolecular collisions seldom happen.

The biggest difference among the three cluster beams lies in their efficiency at producing thin films. The number of incident carbon atoms adhering to the surface in the ethylene cluster beam deposition fluctuates between 10\% and 55\% over the entire range of cluster energy and incident angle (Figure 4-4), while the number of incident carbon atoms adhering to the surface from the adamantane and C\textsubscript{20} beam depositions is 20\%-
80% and 35%-94%, respectively (see Figure 4-7 and 4-9). Under the same deposition conditions, C\textsubscript{20} is the most efficient cluster at generating amorphous thin film, while the ethylene clusters are the least efficient species. This can be explained by the differences in the molecular binding energy and the overall reactivity of these species. The molecular binding energy of ethylene is 23.6 eV/molecule, adamantane is 112 eV/molecule, and C\textsubscript{20} is 118 eV/molecule. Thus, despite the strain in the fullerene, C\textsubscript{20} is the most difficult molecule to smash apart. Consequently, a relatively big fragment from C\textsubscript{20} can survive the deposition process. If an atom in the fragment is active enough to be bonded to the substrate, the whole fragment will adhere to the substrate, which will result in a very efficient thin film formation. The reactivity of the atom in the cluster is determined by the overall reactivity of each cluster, which is related to the saturation of the carbon atoms in the molecules and the external kinetic energy (i.e., the incident energy) per molecule as compared to the molecular binding energy.\cite{95} While ethylene and C\textsubscript{20} both contain unsaturated carbon atoms, adamantane does not. The lowest incident energy considered in this study is $E_{\text{total}} = 400$ eV/cluster (in the case of the ethylene clusters, it is 50 eV/molecule since there are eight ethylene molecules in each cluster). This energy is about 2.1 times of the ethylene molecular binding energy, while it is at least 3.4-3.5 times the molecular binding energy of adamantane and C\textsubscript{20}. The highest incident energy considered here is $E_{\text{total}} = 1600$ eV/cluster, corresponding to the deposition at 60° with a constant incident energy of 400 eV/cluster normal to the surface. This energy is about 8.5 times of the ethylene molecular binding energy, while at least 13.6-14.3 times of the molecular binding energy of adamantane and C\textsubscript{20}. Therefore, at the same incident energy,
the atom in $C_{20}$ appears to be the most reactive atom. In other words, $C_{20}$ is the most efficient species for thin film generation.

More differences can be found by studying the change of the adhesion percentage with the incident angle and energy. When the incident energy normal to the surface is 400 eV/cluster, the total incident energy is about 428 eV/cluster at 15°, 800 eV/cluster at 45° and 1600 eV/cluster at 60°. So the energy considered for 15° depositions does not change a lot (400 eV/cluster vs. 428 eV/cluster). That is why all three species show similar amounts of adhesion at 15° when the depositions occur at the two sets of deposition energies. However, the total incident energy is enhanced dramatically at 45° and 60° when the energy is kept at 400 eV/cluster normal to the surface. At these large angles, as expected, ethylene cluster beams produce significantly higher adhesion when the incident energy is higher (see Figure 4-4) because the ethylene atoms are more reactive at high energy. However, adamantane beams do not show such an increase at 45°, but do have an improvement in the adhesion at 60° when the deposition occurs at an incident energy of 400 eV/cluster normal to the surface (Figure 4-7). While at both 45° and 60°, $C_{20}$ beams generate comparable amount of adhesion at the two sets of incident energies considered, as shown in Figure 4-9. One possible explanation is that if the external kinetic energy is already high enough to break the molecule(s) in the cluster when it is converted into internal kinetic energy upon deposition, the increase in external kinetic energy won’t help to improve the overall reactivity of the cluster molecule(s) even more. Therefore, the number of reactions and the amount of adhesion will not increase. In other words, there exists an optimal incident energy that will result in the highest overall reactivity of the cluster molecule, which in turn will result in the greatest amount of adhesion. From the
results of this study, this optimal incident energy depends on not only the species but also the incident angle.

The simulations of Tang et al. predicted a strong dependence of the deposition result on the initial orientation of the incident species in the $C_{60}$-surface collisions.\textsuperscript{[112]} The solid surface they used is a structureless wall. Thus, this orientation dependence was expected to persist or even intensify when a structured surface was used. While in our study, the depositions of all the three cluster beams on the diamond (111) surface along different orientations result in thin films that are not significantly different from one another. However, this result is not considered to be contrary to Tang’s conclusion, because the species used here are deposited in a beam of twenty randomly oriented clusters, whereas Tang et al. deposited only one $C_{60}$ molecule at a time. Therefore, in our simulations, any possible orientation effects due to the structure of the incident species have been averaged out.

4.4 Conclusions

Classical molecular dynamics simulations have been used to examine the thin film formation through the deposition of cluster beams of ethylene, adamantane, and $C_{20}$ on hydrogen-terminated diamond (111) surface. These results have been reported recently.\textsuperscript{[269, 270]} In summary, during the deposition, the incident species undergo rapid chemical reactions that lead to thin-film formation and surface sputtering. $C_{20}$ is the most reactive species among the three, and therefore, the $C_{20}$ beam is found to be most efficient at producing thin film. The molecular cluster beam of ethylene is the least efficient species. The resultant thin film is essentially amorphous with the majority of carbon atoms sp$^2$-hybridized and connected in a linear manner. Despite the differences in the chemical bonding in the three incident clusters, the structure of the resultant thin film
is predicted to be similar. The effects of incident angle and the incident energy are also documented. In general, increasing the angle causes the amount of thin film nucleation to decrease. However, the incident angle doesn’t affect the film structure. Deposition along various crystallographic orientations is not found to have significant effect on the results.
CHAPTER 5
CHEMICAL MODIFICATION OF CARBON NANOTUBE/POLYMER COMPOSITES THROUGH POLYATOMIC-ION BEAM DEPOSITION

Carbon nanotubes are promising reinforcements in polymer composites because of their remarkable modulus, extraordinary strength and high aspect ratio. The performance of a composite depends critically on the interfacial properties between the reinforcements and the matrix because these properties determine the load transfer ability. The formation of a strong chemical bond between the reinforcing fiber and the matrix is an effective way to ensure successful load transfer from the matrix to the reinforcements. However, previous studies on a number of as-synthesized carbon nanotube/polymer composites showed that untreated nanotubes are usually bonded to the polymer matrix only through relatively weak van der Waals interactions, as a result, the interfacial properties are poor.\textsuperscript{[152, 161, 167, 171-173]} To functionalize the nanotube wall and thus to form cross-links between the nanotube and the matrix are not easy and are often achieved using severe chemical reactions.\textsuperscript{[143, 190, 191]} However, these harsh chemical treatments can simultaneously result in damage to the nanotube structure,\textsuperscript{[144, 190, 191]} which is undesirable because the nanotube may lose its superior properties. Therefore, a method that can modify the nanotube \textit{in situ} is desired. Simulations and experiments have found that at incident energy of 10-80 eV/ion, ion deposition on carbon nanotube bundles can lead to covalent bond formation between nanotubes or adjacent tube walls.\textsuperscript{[199, 200]} Besides, ion irradiation has the obvious advantage over the wet chemical techniques in that it employs no solvents and wastes little reagent,\textsuperscript{[271]} making it an environmentally friendly method.
These previous investigations suggest that ion irradiation of the carbon nanotube-containing composites would be a possible way to form strong chemical bond between the tubes and matrix without pretreating the nanotubes. Therefore, molecular dynamics simulations are used in this study to examine the in situ chemical modification of carbon nanotube/polystyrene composites through the deposition of an energetic \( \text{C}_3\text{F}_5^+ \) beam at room temperature (300 K).

5.1 Simulation Details

The second generation many-body reactive empirical bond order (REBO) potential developed from Abell-Tersoff potential and parameterized by Brenner et al. for hydrocarbon systems\(^{[211]}\) and Sinnott et al. for C-F-H systems\(^{[272]}\) is used to describe the intramolecular interactions in the ions, nanotubes, polymer chains, and cross-links. The long-range van der Waals interactions are considered by coupling the short-ranged REBO potential with the Lennard-Jones (LJ) potential.\(^{[2]}\) REBO potential does not allow for charging of the atoms. Instead, the potential treats the ions as neutral radicals, as is traditionally done in classical MD simulations with empirical potentials.\(^{[4]}\) It is recognized that charge may influence the chemical reactions that occur on deposition. However, it should also be noted that in experiments, the ions would be rapidly neutralized as they approach the substrate due to the existence of background gas or the use of the electron current to avoid ion beam induced charging of the substrate.\(^{[271, 273]}\) This is believed to be especially true for hyperthermal (1-500 eV) and higher incident ion energies.\(^{[271]}\) This approach has been applied to model the related processes of ion bombardment of polymer surfaces\(^{[274, 275]}\) and carbon nanotube bundles\(^{[199, 200]}\) with considerable success.
The polymer matrix considered is polystyrene (PS) because it is among the polymers used to make nanotube/polymer composites in experiments\cite{172,173} due to its well-known properties, structural simplicity, and good processability.\cite{172} A (10, 10) SWNT is embedded in the polymer. This nanotube has a diameter of approximately 1.4 nm, the diameter of a typical nanotube synthesized in the laser-vaporization of graphite.\cite{130} The (10, 10) SWNTs are also believed to be the predominant constituents of nanotube ropes produced by the electric arc technique using a catalyst.\cite{131}

A 3.0 nm long carbon nanotube (CNT) is introduced into the polymer matrix at the center but is embedded at varying depths. The polymer chains are parallel to the nanotube axis, as shown in Figure 5-1(a). This type of composite structure is made by replacing an appropriate number of polymer chains with the nanotube. The system contains 480 carbon atoms in the nanotube, and 59-60 polystyrene chains. The physical dimensions of the composite substrate are 8.0 nm × 5.7 nm × 3.0 nm. Periodic boundary conditions are applied only in the direction of the nanotube axis, which is also the direction of polymer chains. Thus, this model mimics an infinitely long CNT embedded in long chains of PS. In order to determine the possible influence of the nanotube on the ion beam deposition results, a pristine PS substrate of the same dimensions is used.

Another nanotube reinforced composite structure with the polymer chains perpendicular to the nanotube axis (Figure 5-1(b)) is also considered. This type of composite structure is made by replacing a number of polymer segments with the nanotube. The physical dimensions are 5.3 nm × 5.7 nm × 4.6 nm. This system contains a 4.6 nm long nanotube with 840 carbon atoms, and 88 PS chains. Both the nanotube and the polymer chains are infinitely long with periodic boundary conditions applied in both
directions of the nanotube axis and the polymer chains. For simplicity, hereafter, the composite structure with the nanotube parallel to the polymer chains is denoted as CNT/PS-∥, and the structure with the nanotube perpendicular to the polymer chains is CNT/PS-⊥.

Figure 5-1. The composite structures before ion deposition (only parts of the systems are shown for clarity). (a) Carbon nanotube axis parallel to the polymer chains (CNT/PS-∥); (b) Carbon nanotube axis perpendicular to the polymer chains (CNT/PS-⊥).

As displayed in Figure 5-1, the simulations performed here model the ideal situations where the polystyrene matrix has a crystalline structure. It should be noted that amorphous PS other than crystalline PS is most often used experimentally. Therefore, random orientations of the CNT relative to the polymer chains are expected in real experiments. The two orientations considered in this simulation study thus only represent two simple cases out of the numerous situations. It is expected that reasonable predictions would be derived for an amorphous polymer matrix from the results of the deposition on these two CNT-containing composite structures.

For each composite structure, the carbon nanotube is surrounded by the matrix at varying depths to examine the dependence of the modification effects on the location of the nanotube relative to the top of the surface. Three cases are considered. The shallowest
case has only one layer of PS on top of the nanotube, while the deepest one has three layers of polymer covering the nanotube, and the one in-between has two layers of polymer on top of the nanotube. Hence, this simulation study considers the composites where the carbon nanotube is essentially embedded close to the surface.

Before the deposition, all the substrates are first relaxed at 300 K to obtain the energetically optimized structure. As shown in Figure 5-2, after the relaxation, some carbon atoms on the nanotube capture a hydrogen atom from the PS (Figure 5-2(a)), or even “form” a covalent bond to the PS backbone (Figure 5-2(b)). This behavior has been predicted to occur in other molecular dynamics simulations\[181,182\] as well, and is consistent with the predictions of \textit{ab initio} calculations.\[276,277\] This occurs because the nanotube-PS system starts off with some stored energy that is dissipated during the equilibration steps prior to the ion deposition. However, it is not expected that nanotubes in a PS matrix will form covalent bonds to the PS spontaneously in actual composites.

![Figure 5-2. The composite structures after the relaxation while before the ion deposition. The gray spheres are carbon atoms. The white spheres are hydrogen atoms. (a) The circled area shows hydrogen atoms captured by the carbon nanotube during the relaxation; (b) The circled area shows the covalent bond formed between the polymer and the nanotube during the relaxation.](image)

In order to maintain the system temperature at 300 K and prevent the spurious reflection of pressure waves from the borders of the system, the generalized Langevin equation (GLEQ) approach is used to dissipate the extra energy pumped into the system
after the deposition. That is, about two layers of the polymer from the bottom and the atoms within 5-12 Å from the four slab edges have Langevin frictional force and the associated random force applied. The other substrate atoms and the atoms in the ions do not have any constraints and will be treated according to the interactomic potentials described above.

Polyatomic ion deposition can transfer a relatively large concentration of atoms and energy to a very localized region of the surface in a manner that is analogous to the deposition of energetic clusters. Hence, it has higher efficiency to selectively modify the surface region than single-atom ion deposition. Due to the technological importance of surface fluorination, fluorocarbon ions are widely used to modify various substrates. The \( \text{C}_3\text{F}_5^+ \) ion is among the most prevalent ion species generated from many fluorocarbon feed gases.\textsuperscript{[278-280]} Therefore, in this simulation study, the ion beam containing 50 \( \text{C}_3\text{F}_5^+ \) ions is considered. The \( \text{C}_3\text{F}_5^+ \) ion has several isomers. A combined experimental and simulation study on the effect of the \( \text{C}_3\text{F}_5^+ \) ion structure during the ion deposition of polymeric thin films suggested that most of the \( \text{C}_3\text{F}_5^+ \) ions are at the ground state structure, which is \([\text{CF}_2-\text{CF}-\text{CF}_2]^+\).\textsuperscript{[274]} Therefore, this ground state structure of \( \text{C}_3\text{F}_5^+ \) is used in our simulations. The ions are deposited on the substrate at random positions along the surface normal because the normal impact leads to the most reactive collisions.\textsuperscript{[281]} In order to effectively functionalize the carbon nanotube, the ion beam is focused on the area where the carbon nanotube is embedded. Two incident energies of 50 eV/ion and 80 eV/ion are considered. Depending on the incident energy, there is a 2-3 ps time interval between the impacts of any two consecutive depositing ions. In this way, the substrate is allowed to equilibrate between deposition events, and thus well maintain the
system temperature. After the entire ion beam is deposited, the whole system is equilibrated at a higher temperature of 400 K to accelerate the relaxation of the substrate and allow the post-deposition reactions to happen.[274] Then the system is cooled back to 300 K until a steady state is reached. Throughout the whole simulations, 0.2 fs is used as the time step.

5.2 Results

As the ion deposition process progresses, some incident ions dissociate into smaller fragments (ion fragmentation) upon impact or react with each other. Some ions or ion fragments react with the polymer chains, and some react with the embedded carbon nanotube. These are called ion implantation. Other ions or ion fragments get trapped within the polymer matrix but do not form bonds with the PS carbon atoms on the time scales of these simulations. During the relaxation, some initially trapped ions or ion fragments will diffuse out of the substrate and scatter away from the surface, especially at a higher temperature.

Some polymer atoms are sputtered away by the incident ion, leaving an active spot behind either to react with the ion or ion fragment, or, more importantly, to form cross-links to the nanotube or between polymer chains. The original crystalline polymer structure becomes amorphous. During the ion deposition, the carbon nanotube experiences elastic deformation due to the ion impacts but then recovers its initial shape during the equilibration, which can be explained by the remarkable flexibility of the carbon nanotube in the direction perpendicular to the tube axis. Cross-links are predicted to form between the polymer backbone and the nanotube either directly or through an ion/ion fragment, depending on the incident energy and the composite structure. A typical series of events is illustrated in Figure 5-3.
Figure 5-3. A series of snapshots during the ion beam deposition. (a) At time = 0.4 ps, the deposition of the first ion causes the covalent bond formed between the nanotube and the polymer (see the circled area); (b) At time = 2.2 ps, the deposition of the second ion has broken the covalent bond formed before (see the circled area); (c) At time = 2.4 ps, the covalent bond has formed again (see the circled area) and the ions are pushed away by the recovery of the carbon nanotube; (d) At time = 26.4 ps, an incident ion has hit right on the carbon nanotube and caused significant deformation of the nanotube; (e) At time = 26.6 ps, the ion is pushed away into the matrix by the rebounding action of the nanotube. (Black spheres are carbon atoms in the ion, dark gray spheres are fluorine atoms in the ion, light gray spheres are carbon atoms in the substrate, and white spheres are hydrogen atoms in the PS. The same color scheme is applied throughout this whole chapter.)
5.2.1 C₃F₅⁺ Ion Beam Deposition on CNT/PS-// Composites

At the incident energy of 50 eV/ion, the simulations predict the carbon nanotube is chemically functionalized after the deposition when there is only one layer of polymer covering the embedded nanotube, as demonstrated in Figure 5-4(a). Covalent bonds are formed between the nanotube and the polymer matrix. In addition, chemical adsorption of some fluorine atoms and ions or ion fragments on the nanotube wall occurs. In the other two cases where the nanotube is buried deeper, however, neither the formation of new covalent bond between the polymer and the nanotube nor the implantation of ion or ion fragments on the tube wall is observed, as shown in Figure 5-4(b) and (c). Nevertheless, in all the three cases, the ion beam deposition leads to disorder within the PS matrix and creating cross-links between PS chains near the surface.

![Figure 5-4](image.png)

Figure 5-4. The CNT/PS-// composites after the ion beam deposition at 50 eV/ion. (a) The substrate with one layer of polymer on top of the nanotube. (b) The substrate with two layers of polymer on top of the nanotube. (c) The substrate with three layers of polymer on top of the nanotube. (Compare this structure with Figure 5-2(b), where it shows the corresponding structure of CNT/PS-//-3 before the deposition, no new functionalization effects are shown after the deposition.)

Table 5-1 summarizes the results after the deposition of the 50 C₃F₅⁺ ions on these CNT/PS-// composites at the incident energy of 50 eV/ion. In the table, the three
composite substrates are denoted as CNT/PS-//-1, CNT/PS-//-2 and CNT/PS-//-3, referring to the composite with one, two and three layer(s) of polymer covering the nanotube, respectively. As shown in the table, the substrate etching is almost negligible in all the three cases. All the substrate etching comes from the polymer. No atom from the embedded carbon nanotube is lost during the deposition. More than half of the incident ions are scattered back into the vacuum after the deposition. However, among the trapped \( \text{C}_3\text{F}_5^+ \) ions, the amount of the intact ions, i.e., the ion still maintains its ground state structure after the deposition, increases slightly with the increasing depth of the embedded carbon nanotube. The average penetration depth (\( \bar{d} \)) of the incident ions is around 2 nm, and is more or less the same for all the three composites.

Table 5-1. Summary of the results after the ion beam deposition on CNT/PS-// composites at 50 eV/ion.

<table>
<thead>
<tr>
<th>Substrate etching (# of C/ion)</th>
<th>Trapped C atoms from ion (%)</th>
<th># of intact ( \text{C}_3\text{F}_5^+ )</th>
<th>Functionalization of CNT</th>
<th>Cross-links between PS and CNT</th>
<th>( \bar{d} ) (nm)</th>
</tr>
</thead>
<tbody>
<tr>
<td>CNT/PS-//-1</td>
<td>0.3</td>
<td>49.3</td>
<td>7</td>
<td>Yes</td>
<td>Yes</td>
</tr>
<tr>
<td>CNT/PS-//-2</td>
<td>0.1</td>
<td>42.0</td>
<td>11</td>
<td>No</td>
<td>No</td>
</tr>
<tr>
<td>CNT/PS-//-3</td>
<td>0.2</td>
<td>40.1</td>
<td>12</td>
<td>No</td>
<td>No</td>
</tr>
</tbody>
</table>

Figure 5-5 demonstrates the chemical bonding status of those trapped ion and ion fragments. This is of interest because it gives detailed information on the dissociation reaction of the ions and how the ion or ion fragments react with each other or the substrate atoms. This information can be compared with experimental XPS (X-ray photoelectron spectroscopy) spectrum, which is usually used in surface science to determine chemical composition and detect the change of the chemical environment of the atom. As shown in these figures, the predominant ion species after the deposition at 50 eV/ion is \( \text{C}_3\text{F}_5 \), and most of the ion species remain unbonded.
Consistent with the results of ion irradiation of carbon nanotube bundles,\cite{199, 200} more significant chemical modification of the nanotube in the composites occurs at a high incident energy of 80 eV/ion. The nanotube in CNT/PS-//-1 is the most easily functionalized. More covalent bonds are formed between the nanotube and PS matrix, and more ion species are chemically adsorbed than at 50 eV/ion, as shown in Figure 5-6(a). At 80 eV/ion, both cross-link formation and the implantation of ion species on the nanotube wall are observed in the composite where the nanotube is buried with two
layers of polymer on top of it, as shown in Figure 5-6(b). Although no new bond is created between the nanotube and the PS, the nanotube in CNT/PS-//-3 has captured a fluorine atom (Figure 5-6(c)), which also demonstrates an improvement in the functionalization efficiency at a high incident energy.

Figure 5-6. The CNT/PS-//- composites after the deposition at 80 eV/ion. (a) CNT/PS-//-1; (b) CNT/PS-//-2; (c) CNT/PS-//-3.

Table 5-2. Summary of the results after the ion beam deposition on CNT/PS-//- composites at 80 eV/ion.

<table>
<thead>
<tr>
<th></th>
<th>Substrate etching (# of C/ion)</th>
<th>Trapped C atoms from ion (%)</th>
<th># of intact C$_3$F$_5$ $^+$</th>
<th>Functionalization of CNT</th>
<th>Cross-links between PS and CNT</th>
<th>$\bar{d}$ (nm)</th>
</tr>
</thead>
<tbody>
<tr>
<td>CNT/PS-//-1</td>
<td>1.2</td>
<td>37.3</td>
<td>4</td>
<td>Yes</td>
<td>Yes</td>
<td>2.5</td>
</tr>
<tr>
<td>CNT/PS-//-2</td>
<td>1.2</td>
<td>38.7</td>
<td>1</td>
<td>Yes</td>
<td>Yes</td>
<td>2.9</td>
</tr>
<tr>
<td>CNT/PS-//-3</td>
<td>1.3</td>
<td>54.7</td>
<td>5</td>
<td>Yes</td>
<td>No</td>
<td>3.3</td>
</tr>
</tbody>
</table>

The results after the ion deposition at 80 eV/ion on CNT/PS-//- composites are summarized in Table 5-2. As compared with the results at 50 eV/ion (Table 5-1), the substrate etching of the polymer matrix is an order of magnitude higher; the average penetration depth of the ion is larger; while the number of intact C$_3$F$_5$ $^+$ ions is much less; the percentage of the trapped ions is lower for both CNT/PS-//-1 and CNT/PS-//-2 composites at this high incident energy but not for the CNT/PS-//-3 composite. At 80 eV/ion, the predominant trapped ion species in all the three composites is CF$_2$ instead of C$_3$F$_5$, and more ion species are bonded to either the polymer chains or the nanotube, as
shown in Figure 5-7. The increase in the amount of the ion species bonded to the nanotube again demonstrates the improved efficiency of the chemical functionalization of the carbon nanotube at a high incident energy.

Figure 5-7. The normalized chemical bonding information of the trapped ion species after the deposition on CNT/PS-//- composites at 80 eV/ion. (a) CNT/PS-//-1; (b) CNT/PS-//-2; (c) CNT/PS-//-3.

5.2.2 C\textsubscript{3}F\textsubscript{5}\textsuperscript{+} Ion Beam Deposition on Pristine PS Substrates

Table 5-3 compares the results of the ion deposition on pristine PS substrate at 50 eV/ion and 80 eV/ion. As is the case in the deposition on the CNT/PS-//- composites, the
substrate etching effect is much higher and the ion can go deep at a high incident energy, however, the number of intact ions and the amount of trapped incident ions are less. This agrees with the increased reactivity of the incident ions at a high energy.

Table 5-3. Summary of the results after the ion beam deposition on pristine PS substrates at 50 eV/ion and 80 eV/ion.

<table>
<thead>
<tr>
<th>Substrate etching (# of C/ion)</th>
<th>Trapped C atoms from ion (%)</th>
<th># of intact C3F5+</th>
<th>$\overline{d}$ (nm)</th>
</tr>
</thead>
<tbody>
<tr>
<td>50 eV/ion</td>
<td>0</td>
<td>63.3</td>
<td>13</td>
</tr>
<tr>
<td>80 eV/ion</td>
<td>2.0</td>
<td>40.7</td>
<td>3</td>
</tr>
</tbody>
</table>

In order to compare with the deposition results of the composites, the bonding status of the trapped ion species within the pristine PS substrates is also analyzed, as summarized in Figure 5-8. In agreement with what happens in the composites, at 50 eV/ion, the majority of the ion species is C3F5, and most of the ions or ion fragments remain unbonded. In contrast, at a high energy of 80 eV/ion, the major ion species is CF2, and the amount of bonded ion species increases.

![Figure 5-8](image-url)

Figure 5-8. The normalized chemical bonding information of the trapped ion species after the deposition on pristine PS substrates at (a) 50 eV/ion and (b) 80 eV/ion.
5.2.3 $\text{C}_3\text{F}_5^+$ Ion Beam Deposition on CNT/PS-⊥ Composites

Figure 5-9. The CNT/PS-⊥ composites after the ion beam deposition at 50 eV/ion. (a) The substrate with one layer of polymer on top of the nanotube (CNT/PS-⊥-1). (b) The substrate with two layers of polymer on top of the nanotube (CNT/PS-⊥-2). (c) The substrate with three layers of polymer on top of the nanotube (CNT/PS-⊥-3).

As shown in Figure 5-1, there is more room around the embedded carbon nanotube in the CNT/PS-⊥ composite structure than in the CNT/PS-∥ structure. Therefore, after ion beam deposition on the CNT/PS-⊥ composite, the incident ions can gather around the nanotube without being pushed back into the matrix once they pass through the polymer layers, as indicated in Figure 5-9. It is the easiest for the carbon atoms in the nanotube to react with the incident ions when there is only one layer of polymer covering the nanotube (CNT/PS-⊥-1), which is analogous to what is predicted to occur for the CNT/PS-∥ composites. At the incident energy of 50 eV/ion, although multiple chemisorption of ion species on the carbon nanotube is predicted to occur in both CNT/PS-⊥-1 and CNT/PS-⊥-2 composites, as demonstrated in Figure 5-9(a) and (b), respectively, no covalent bond between the nanotube and the polymer matrix is predicted to form between the nanotube and the polymer matrix. No sign of chemical

* Only the depositions at 50 eV/ion on CNT/PS-⊥ composites have been studied so far.
functionalization of the nanotube is observed when there are three layers of polymer on top of the nanotube (Figure 5-9(c)).

Table 5-4. Summary of the results after the ion beam deposition on CNT/PS-⊥ composites at 50 eV/ion.

<table>
<thead>
<tr>
<th>Substrate etching (# of C/ion)</th>
<th>Trapped C atoms from ion (%)</th>
<th># of intact C₃F₅⁺ ion</th>
<th>Functionalization of CNT</th>
<th>δ (nm)</th>
</tr>
</thead>
<tbody>
<tr>
<td>CNT/PS-⊥-1</td>
<td>0.2</td>
<td>61.2</td>
<td>16</td>
<td>Yes</td>
</tr>
<tr>
<td>CNT/PS-⊥-2</td>
<td>0.2</td>
<td>74.7</td>
<td>15</td>
<td>Yes</td>
</tr>
<tr>
<td>CNT/PS-⊥-3</td>
<td>0.3</td>
<td>57.3</td>
<td>17</td>
<td>No</td>
</tr>
</tbody>
</table>

The results of the ion deposition at 50 eV/ion on the three CNT/PS-⊥ composites are summarized in Table 5-4. At this incident energy, the substrate etching effect is not significant and no carbon atom from the carbon nanotube is knocked out of the substrate. More than 50% of the incident ions are caught either by the polymer or by the nanotube. Among the trapped ion species, the number of intact incident C₃F₅⁺ ion is more than that in CNT/PS-∥ composites. The average penetration depth of the incident ion is about 3 nm, 1 nm deeper than the deposition on the CNT/PS-∥ composites at the same incident energy. The chemical bonding information of the trapped ion species is demonstrated in Figure 5-10. In behavior that is consistent with what occurs after deposition on the CNT/PS-∥ composites and the pristine PS substrate, the major ion species is C₃F₅, and only a small amount of the ion species is bonded to the polymer or the nanotube.

5.3 Discussion

It has been experimentally shown that electron or ion irradiation of carbon nanotube may cause dramatic shrinkage in the nanotube diameter when the incident energy is high enough."[193] Theoretical studies indicate that the reason for this is the removal of the carbon atoms from the nanotube wall through the irradiation."[193] At the two incident energies used in this study, no carbon atom from the embedded nanotube is
Figure 5-10. The normalized chemical bonding information of the trapped ion species after the deposition on CNT/PS-⊥ composites at 50 eV/ion. (a) CNT/PS-⊥-1; (b) CNT/PS-⊥-2; (c) CNT/PS-⊥-3.

found to be knocked out and the substrate etching is solely from the polymer, therefore, although the embedded carbon nanotube deforms after the deposition, the diameter is still around 1.4 nm.

This series of simulations predict that energetic ion beam deposition can indeed lead to the formation of cross-links between the carbon nanotube and the polymer matrix under appropriate deposition conditions. It is found that the chemical functionalization
efficiency of the carbon nanotube depends largely on the incident energy of the ions and the composite structure.

5.3.1 The Effect of the Incident Energy

During the deposition, part of the external kinetic energy of the incident ion is transformed into its internal kinetic energy, and part of it is transferred to the substrate. When the internal kinetic energy of the ion is high enough to overcome its binding energy, fragmentation of the ion occurs. At a moderate incident energy of 50 eV/ion, the transformed internal energy after the deposition is not high enough to break the strong C-C bonding for most incident ions, as a result, the majority of the ion species in the substrate remain as $C_3F_5$. In contrast, at 80 eV/ion, more external kinetic energy is transformed into internal kinetic energy of the ion, thus, smaller ion fragments, such as CF$_2$, prevail after the ion deposition, and the number of intact $C_3F_5^+$ ions dramatically decreases. This behavior is apparent in the deposition on the composites (Figures 5-5 and 5-7, and Tables 5-1 and 5-2) as well as on the pristine polymer substrates (Figure 5-8 and Table 5-3).

High incident energy also means more energy will be transferred to the substrate and thus activate the substrate atoms. Therefore, the amount of substrate etching increases substantially when the incident energy is high. In the case of carbon nanotube composites, the carbon atoms on the nanotube wall may be activated if the energy has not decayed too much. At the high incident energy of 80 eV/ion, more cross-links are predicted to form between the nanotube and the polymer matrix (Figure 5-6), and the number of ion species bonded to the carbon nanotube increases (Figure 5-7). These indicate the improved reactivity of both the ion species and the carbon atoms on the tube wall when the deposition occurs at a high energy. This, in turn, results in an enhanced
chemical modification efficiency of the carbon nanotube at a high energy, especially in the case where there is only one polymer layer on top of the embedded nanotube.

For those ions or ion fragments that do not react with polymer chains or the nanotube, collision may happen between them and the substrate atoms. Therefore, the momentum of these incident particles will change. Some will move upward instead of penetrating deeply into the composite. Once the instantaneous movement of the polymer chains opens a large enough passage, some of these trapped ions or ion fragments will diffuse out of the substrate. Others, which either do not find the right passage or do not have enough energy to escape, remain trapped in the substrate.

For both the composite substrate (for example, CNT/PS-//-1 and CNT/PS-//-2 composites) and the pristine polymer, the percentage of the incident ions remaining within the substrate after the deposition is lower at a high incident energy. There are two reasons for this. First, the remaining external kinetic energy of the ion species is high when the initial incident energy is high. Second, at a high incident energy, more ions will dissociate into small ion fragments, which has been demonstrated in Figure 5-7 and 5-8(b). It is therefore easier for these small ion fragments to find the lowest energy “escaping” passage.

Nevertheless, the deposition on CNT/PS-//-3 composites at 80 eV/ion yields a higher fraction of the trapped ion species than the deposition at 50 eV/ion. A repeated simulation of the deposition on CNT/PS-//-3 composite at 80 eV/ion gives a similar percentage of the trapped ion species, which is about 56.0%. One possible reason is the effective channeling of the incident particles in the CNT/PS-//-3 composite when the incident energy is 80 eV/ion. In other words, this effective channeling is not only related
to the specific substrate structure but also related to the incident energy of the ion beam.

In addition, the final composite structure generated from the repeated simulation, as given in Figure 5-11, shows that the incident ion species tend to approach the embedded CNT, which is somehow not clearly shown in Figure 5-6(c). This tendency may lead to an efficient dissipation of the ion energy because CNT has a comparable thermal conductivity to the diamond. Therefore, the ion species may quickly lose their energy and finally get trapped within the substrate.

![Figure 5-11. The CNT/PS—//-3 composite structure after the deposition at 80 eV/ion generated from the repeated simulation.](image)

The incident energy is also found to determine the penetration depth of the incident ion in that both results of the deposition on the pristine polymer substrates (Table 5-3) and the composites (Tables 5-1 and 5-2) show that at the same incident energy, the average penetration depth of the incident ions is about the same. As expected, high incident energy leads to a deep penetration.

### 5.3.2 The Effect of the Composite Structure

The simulations predict that, under the same deposition conditions, 10-30% more incident ions get trapped after the deposition on the composites where the carbon nanotube is introduced with its axis perpendicular to the polymer chains (see Table 5-4) than the composites where the carbon nanotube axis is parallel to the polymer chains (see
Table 5-1). What is particular is that these trapped ion species tend to surround the nanotube in CNT/PS-⊥ composites (see Figure 5-9). In addition, the ions can go deeper and more incident C$_3$F$_5^+$ ions maintain the original ground state structure in the case of the deposition on CNT/PS-⊥ composites (compare Tables 5-4 and 5-1). As indicated in Figure 5-1, the CNT/PS-⊥ composite structure is not such a compact structure as the CNT/PS-// composite in that the average distance between the nanotube and the surrounding polymer chains in CNT/PS-⊥ is around 3 Å longer than that distance in CNT/PS-//. The relatively large empty space between the nanotube and the polymer matrix in CNT/PS-⊥ composites provides wide channels for the ions to go deep without collision and resistance. As a result, more incident ions can survive and remain within the substrate. In the CNT/PS-⊥ composites, the space around the carbon nanotube is 4.3 – 8 Å, beyond the van der Waals repulsion distance (3.0 – 3.5 Å); therefore, it is possible for more incident ions to approach the embedded carbon nanotube in the CNT/PS-⊥ composites. Such gathering-around of the ions about the nanotube facilitates the chemical adsorption of the ion species on the nanotube wall and makes it possible to bridge between the polymer chains and the nanotube via these ion species if the ion energy is high enough. However, at 50 eV/ion, the nanotube is not predicted to cross-link to the polymer in the deposition on CNT/PS-⊥ composites because the tube is far removed from the polymer matrix.

If amorphous PS instead of crystalline PS is used, based on the deposition results of the two composite structures considered in this simulation study, it is anticipated that a high fraction of the incident ion species will get trapped between the polymer chains because there is more free volume in amorphous polymer than in crystalline polymer.\[282\]
On the other hand, the large empty space around the embedded nanotube as shown in Figure 5-1 may be filled with polymer chains if the polymer matrix is amorphous. In other words, the embedded CNT could be close to the surrounding polymer; therefore, it might become even more likely to induce the formation of cross-links between the nanotube and the amorphous polymer matrix after the ion beam deposition.

The depositions on composites with the carbon nanotube embedded at varying depths show a clear dependence of the functionalization efficiency on the location of the nanotube within the matrix relative to the top of the surface. Figure 5-12 plots the fraction of the functionalized carbon atoms on the carbon nanotube wall as a function of the depth under various deposition conditions. Obviously, it is difficult to modify the carbon nanotube when it is buried deep within the matrix because of the rapid energy decay.

![Graph showing the fraction of functionalized carbon atoms in the carbon nanotube embedded at varying depths.](image)

**Figure 5-12.** The fraction of functionalized carbon atoms in the carbon nanotube embedded at varying depths.

In this study, once the carbon atom on the nanotube wall gets functionalized, it typically changes from sp² hybridization to sp³ hybridization either from the attachment...
of ion species or by forming cross-links to the polymer chains. Although there is no damage to the nanotube wall, such as the creation of vacancy, predicted at the energy level used here, the change of the hybridization does introduce local deformation since the local bond length changes from 0.14 nm to 0.15 nm$^{200}$ and the bond angle approaches the tetrahedral angle.$^{243}$ It is of concern that such “defects” on the tube wall may destroy the desirable mechanical properties of the carbon nanotube to be used as the reinforcement. A previous computational work by Garg and Sinnott showed that if the fraction of the rehybridized carbon atoms in a (10,10) tube is about 5.2%, the functionalization would decrease the stiffness of the nanotube by 15%.$^{223}$ However, if the introduction of the functionalized carbon is less than 1%, the change in tensile strength of the nanotube is negligible.$^{182}$ Unfortunately, it is still an open question as to the upper limit of rehybridized carbon atoms that would not induce a significant reduction in the mechanical properties of carbon nanotube. The highest functionalization probability given in Figure 5-12 is about 2.5%, but in most cases, the fraction is less than 1%. Therefore, it is expected that the functionalized carbon nanotube obtained after the ion beam deposition in this study still possesses its remarkable mechanical properties.

5.3.3 Comparison between Pristine Polymer Substrates and Composites

A recent experimental study has compared the surface modification of CNT/PAN (polyacrylonitrile) composite films and pure PAN films by proton beam bombardment.$^{283}$ This study indicated that the introduction of CNT would influence both the chemical and structural modifications induced by the proton. Similar results are obtained from our simulations of ion beam bombardment on CNT/PS composites and pristine PS substrates. Due to the presence of the carbon nanotube, some phenomena that occur in the composites are different from what happens in the pristine polymer, although
ion depositions on pristine PS substrates and the composites also display similar behavior, such as the strong dependence of the modification efficiency on the incident energy.

As summarized in Tables 5-1, 5-2 and 5-3, if the deposition results of CNT/PS-// composites and pristine PS substrates are compared, the overall trapped ion percentage is found to be lower in the carbon nanotube composites than in the pristine polymer at the same incident energy: 10-20% lower in the case of the deposition at 50 eV/ion and ~5% lower in the case of the deposition at 80 eV/ion (except the CNT/PS-//-3 composite). In the CNT/PS-// composites, several polymer chains are replaced by the CNT. Although small ion species can find room between the polymer chains, as what happens in the pristine polymer substrates, their capability to penetrate into the CNT is limited if the incident energy is not high enough. In fact, at both 50 eV/ion and 80 eV/ion, no ion or ion fragment is found inside of the CNT in this study. Therefore, the replacement of the polymer chains by the nanotube practically excludes a considerable area for possible ion penetration, which results in a lower percentage of trapped ions in the composites.

However, it is noted that the depositions on CNT/PS-⊥ composites at 50 eV/ion actually have comparable trapped ion percentages to the pristine polymer substrate. As discussed in Section 5.3.2, the reason is the channeling effect due to the available space around the CNT in CNT/PS-⊥ composite structure, which essentially compensates for the excluded area enclosed by the CNT.

As the simulations indicate, all the substrate etching comes from the top several layers of polymer. Although the substrate etching depends mainly on the incident energy, the presence of carbon nanotube is also found to affect this property especially at a
relatively high incident energy. As indicated in Table 5-2 and Table 5-3, at 80 eV/ion, the amount of the substrate etching in the pristine polymer substrate is about 1.7 times as much as that in the CNT/PS-// composites. The lower substrate etching in the composites can find explanations from the remarkable thermal properties of the carbon nanotube. The high thermal conductivity of the carbon nanotube facilitates the effective dissipation of the energy; consequently, fewer substrate atoms in the composites will gain high enough energy to sputter away from the surface.

5.4 Conclusions

In composite materials, cross-links between the reinforcements and the matrix will improve the load transfer capability between these two phases. This computational study has demonstrated that when the reinforcing carbon nanotube is embedded close to the surface, polyatomic ion beam deposition at incident energies of 50-80 eV/ion can induce the formation of cross-links between the otherwise unfunctionalized carbon nanotube and the polymer matrix without too much damage to the original composite structure. It thus encourages experimental trials using the energetic ion beam deposition or related techniques to effectively harness the outstanding mechanical properties of the carbon nanotube to produce high-performance composite materials. However, due to the rapid energy decay within the substrate, this technique may only be effective at surface modification. The simulations predict the favorable conditions for efficient chemical functionalization of the carbon nanotube, such as high incident energy and compact composite structure in which the reinforcing carbon nanotube is close enough to the matrix. It has also shown that the response of a carbon nanotube/PS composite to ion beam deposition is different from the response of a pristine PS substrate. The simulations
reveal the atomic-scale mechanisms that are responsible for these differences. Part of these results have been reported in Reference [284].

Since this simulation study is highly computationally intensive, only one trajectory has been carried out for most substrates. It is recognized that the reported quantitative results may lack the statistical reliability, however, the qualitative predictions, which are the major focus of this study, are believed to be correct.
CHAPTER 6
CONCLUSIONS AND BEYOND

6.1 General Conclusions

The collision of energetic particles and solid surfaces is one of the most interesting topics in the area of particle-surface interactions. Such techniques include plasma deposition, laser ablation, chemical vapor deposition, cluster beam deposition, and ion beam deposition. Depending on the deposition conditions, a wide range of phenomena can be found, such as implantation, fragmentation, surface sputtering, surface cleaning, phase transition, and, more significantly, impact-induced chemical reactions within the incident species as well as between the incident particle and the surface. Such techniques are widely used to generate thin films and have also found promising application in surface modification. Undoubtedly, experimental studies in this field have improved our understanding of how the changes in deposition method, starting material, and impact conditions influence the results. However, the atomistic mechanisms of the process are not easily obtained from the experimental data and there is much that is not well understood about the process of thin film nucleation and surface modification. In this respect, molecular dynamics simulations provide a powerful and complementary tool to the experimental findings. Particle-surface collisions are especially suitable for study by MD simulations because this process typically occurs within a few picoseconds.

In this dissertation, thin film formation through the deposition of organic cluster beams and the impact induced chemical functionalization of carbon nanotube/polystyrene composites via polyatomic ion beam deposition are investigated using MD simulations.
In the simulations, the interatomic forces are calculated from the reactive empirical bond-order (REBO) potential coupled with the long-range Lennard-Jones potential. The REBO potential allows covalent bond breaking and reforming with associated changes in atomic hybridization. This is crucial for a realistic treatment of organic chemical reactions in an empirical approach. The REBO potential has been shown to be quite good at characterizing reactive processes involving thousands of atoms, but it is not able to describe processes that depend on the explicit and self-consistent inclusion of electrons. These elements, however, are considered in the tight-binding approach, which thus gives more accurate quantitative results than the empirical schemes. In order to obtain a better knowledge of the reliability of the REBO potential to describe the energetic particle-surface collisions, the deposition of hydrocarbon clusters on diamond surfaces is first modeled using both the REBO potential and the order-N nonorthogonal tight-binding (O(N)/NOTB) method of Jayanthi, Wu, et al. The quantitative results of these two methods do not agree perfectly well with each other. The differences in the predictions indicate that as compared to the NOTB Hamiltonian, the REBO potential predicts a higher repulsive barrier, and hence may not be sufficiently flexible to describe all the relevant processes of bond-breaking and bond-forming. However, the qualitative predictions are comparable. Therefore, this comparison study shows that the REBO potential does indeed capture the general characters of carbon-based chemistry.

For constant temperature simulations, appropriate temperature control methods that can effectively dissipate the extra energy must be incorporated in the simulation. One specific role played by these temperature control methods in modeling particle-surface collisions is to absorb the wave reflected from the boundary of the simulation system. In
this dissertation, four temperature control methods are investigated in simulations of carbon cluster deposition. These four methods are the generalized Langevin equation (GLEQ) approach, the Berendsen method, a modified GLEQ approach where an extra damping mechanism is introduced, and a combined thermostat of the GLEQ approach and the Berendsen method. The temperature control capability and the effectiveness to reduce the amplitude of the reflected wave of these methods are compared and discussed. Among the four, the Berendsen method is effective at removing the excess energy at the early stage but the resultant equilibrium properties are not always optimum. It is found that the realistic performances of these methods depend on the cluster incident energy and the substrate size in the simulation. If the substrate is big enough and the incident energy is not too high, the GLEQ approach is sufficient for removal of excess energy. However, the modified GLEQ approach and the combined thermostat perform better than the regular GLEQ approach and the Berendsen method when the incident energy is high.

Collisions between clusters and solid surfaces can produce high quality thin films with various predetermined properties when the deposition conditions are carefully chosen. Our group has previously used MD simulations to examine the deposition of organic molecular clusters of ethane, ethylene, acetylene, and adamantane on diamond surfaces. The chemical reactions among the incident molecules and between the impact cluster and the surface have been studied. Film nucleation and growth have been shown to depend on deposition conditions such as molecular reactivity, cluster size, incident energy, impact frequency, surface reactivity, and surface temperature. In this dissertation, MD simulations using the REBO potential are performed to build on the previous studies and investigate thin film
generation from the deposition of beams of organic clusters with different intracluster bondings. The cluster beams considered include a molecular cluster beam of ethylene held together by van der Waals interactions, a beam of adamantane molecules held together by pure sp$^3$ covalent bonds, and a beam of C$_{20}$ fullerenes held together by sp$^2$ covalent bonds with distorted p-orbitals. In addition, the effects of cluster incident angle and deposition direction are investigated. Therefore, depositions at various angles and lateral momenta along two different crystallographic orientations are considered. The C$_{20}$ is found to be the most efficient species at producing an amorphous thin film. Despite the differences in the chemical bonding within the three incident clusters, the structures of the resultant thin films are predicted to be similar. Deposition at a large incident angle reduces the efficiency of thin film formation. However, the incident angle does not affect the resultant thin film structure. Furthermore, deposition along different crystallographic orientations is not found to have significant influence on the simulation results due to the randomization of the clusters within the beam in both translational and angular orientations.

Since the discovery of carbon nanotubes in the early 1990s, active research has been carried out on this new type of materials because of their unique mechanical and electrical properties. There has been considerable effort spent to incorporate carbon nanotubes into polymer matrix to make use of their extraordinary modulus and resistance to brittle failure. But when as-synthesized nanotubes are used, the composites fail through nanotube pullout due to poor adhesion between the nanotube and polymer matrix.$^{[164,171,173]}$ However, nanotubes that are chemically functionalized adhere more strongly to the polymer matrix because of efficient load-transfer through covalent bonds between the
polymer and the nanotube. Both experimental and computational studies have found that energetic deposition of polyatomic ions can lead to covalent bond formation between nanotubes or adjacent tube walls. Therefore, in the present work, chemical functionalization of carbon nanotube/polystyrene composite via polyatomic ion beam deposition at incident energies of 50-80 eV/ion is investigated using MD simulations. The simulation results show that this approach is suitable for inducing covalent cross-links between otherwise unfunctionalized nanotube and a polymer matrix to toughen the composite. High incident energy and compact composite structures are predicted to be best for effective chemical functionalization of the nanotube. The simulations also show that the introduction of carbon nanotubes will influence both the chemical and structural modifications induced by the ion beam when the deposition results of the composites and pure polystyrene substrates are compared. Most importantly, the simulations reveal the likely atomistic mechanisms responsible for these findings.

These MD simulation studies provide valuable information about the types of chemical reactions that occur upon deposition, detail the atomistic mechanisms responsible for these reactions, and reveal the dependence of the chemical reactions and products on a number of factors including deposition species, incident angle, impact energy, substrate structure, etc. These studies provide an enhanced understanding of the particle-surface interactions and the processing of materials through cluster and/or ion beam deposition. The predictions could lead to improvements in thin film generation and material modification techniques that are used to manufacture and design a variety of products, from microelectronic devices to medical implants. The simulation results of the
deposition on carbon nanotube/polystyrene composites could have important implications for the production of lightweight, high-strength nanocomposites with improved load-bearing capabilities.

### 6.2 Future Work

Throughout this whole dissertation, many of our motivating questions have been answered affirmatively. MD simulations can successfully keep track of the short time scale processes that occur during cluster-surface reactions. However, some subsequent events (for example, thermally activated atomic migration and surface diffusion), which are very important in determining thin film growth and equilibrium structure, may not be rapid enough to be captured by conventional MD simulations. A previous study investigated the subsequent structural relaxation of the resultant thin film by performing geometry relaxation through energy minimization for some representative thin-film fragments.\[101\] In this study, it was found that the structures of the fragments only changed slightly from the relaxed structure predicted in the MD simulations. However, to single out the thin-film fragments has introduced significant simplifications that may not represent the situation where those fragments are connected to the remaining structure. Besides, in order to model the entire deposition process, most MD simulations (including the simulations reported in this dissertation) use deposition rates that are typically 8-11 orders of magnitude higher than the experimental deposition rates.\[286\] Consequently, if the employed thermostat is not effective enough at removing extra energy from the system, the collisions of consecutive incident particles may affect each other directly in ways that they would not at a low deposition rate.

In order to solve all these problems, a hybrid simulation as presented by Jacobsen et al.\[287\] for metal systems could be used. In this hybrid simulation, MD simulation
methods are combined with MC (Monte Carlo) simulation methods. In this way, the short
time scale collision events can be modeled using MD simulations while, the long time
scale events between the collisions, such as surface diffusion and structure relaxation, can
be simulated using MC simulation methods. This hybrid simulation method is time
consuming, but it allows for a more realistic simulation of the collision at a realistic
deposition rate and can predict a more precisely relaxed structure after the deposition.

Another intriguing method is the temperature-accelerated dynamics (TAD)
developed by Sørensen and Voter.[288] This method is based on harmonic transition state
theory and is a combination of conventional molecular dynamics and statistical
mechanics. The main idea behind this method is to study the thermally activated behavior
of the system by performing an MD simulation at a higher temperature rather than at
ordinary temperatures. Therefore, the rate of the activated processes can be raised and
become accessible to the simulation. Of course, raising the temperature may also induce
transitions that may not occur at the ordinary temperatures. Such temperature-induced
bias is corrected by only allowing those transitions that should take place at the ordinary
temperature to occur. In this way, the accessible time scale is extended by orders of
magnitude while the correct dynamics is still maintained.

Simulations that can model the deposition process at an experimental deposition
rate and simultaneously address the questions such as atomic migration and surface
diffusion will give direct insight into the whole experimental process and provide a more
complete picture. Hence, the advanced methods mentioned above are certainly promising
and worth the further exploration and extension to covalently bonded materials.
LIST OF REFERENCES


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BIOGRAPHICAL SKETCH

Yanhong Hu was born on November 28, 1972, in Shanghai, P. R. China. Her father is an engineer, and her mother is an accountant. She grew up in Wuxi, a beautiful city near Shanghai. After her graduation from high school in 1991, she enrolled in the East China University of Science and Technology. During her freshman and sophomore years, she became interested in materials science and engineering, which led her to choose the College of Materials and major in polymer science and engineering. After she graduated with a bachelor’s degree in 1995, she continued her graduate study in the same university and majored in polymer processing. Three years later, she graduated with her master’s degree and worked in Shanghai Huayi (Group) Company as an engineer. In 1999, she was admitted to the Ph.D program in the Department of Chemical and Materials Engineering at the University of Kentucky and joined Dr. Sinnott’s group. In 2000, she transferred to the University of Florida and was admitted to the Department of Materials Science and Engineering, to continue work on her Ph.D degree.